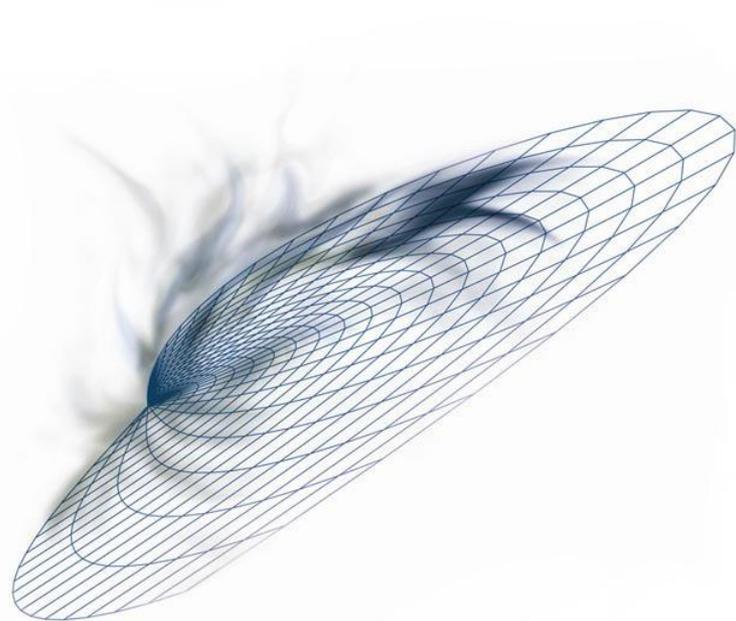


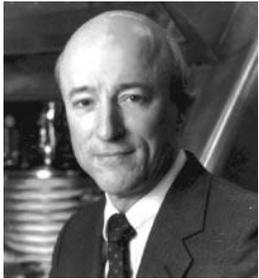
# Multivariate Inverse Methods for Magnetoquasistatic and Electroquasistatic NDE

Dr. Neil Goldfine and Dr. Yanko Sheiretov

**JENTEK Sensors, Inc.**,  
110-1 Clematis Avenue, Waltham, MA  
Phone: 781-642-9666  
Email: [jentek@shore.net](mailto:jentek@shore.net)



# History & Acknowledgements



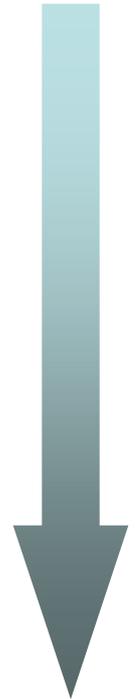
Professor James R. Melcher      1970's and 80's



Dr. Neil Goldfine  
Dr. Andrew Washabaugh      1980's through 2009



Dr. Yanko Sheiretov  
Dr. Darrell Schlicker      1990's through 2009



***For research at MIT LEES, initially under the late Prof. James Melcher and more recently under Prof. Marcus Zahn, and continued at JENTEK Sensors, Inc.***

# History & Acknowledgements (continued)

We would like to acknowledge funding from the US Air Force and the US Navy in particular, as well as other agencies, including, Army, NASA, DOE, DOT and DARPA.

*We believe we have delivered a substantial return on investment for this government funding*

# A Two Part Presentation

## Dr. Neil Goldfine

### Introduction to

- Design, Calibration, Measurement, Inverse Methods, Filters, Decisions
- MWM and MWM-Array Sensors & IDED and IDED-Array Sensors
- Applications (cracks, coatings, corrosion, stress, temperature)
  - Grids and Lattices for Multivariate Inverse Methods
  - Air and Reference Calibration
  - Signature Libraries & Time-Sequenced Imaging for Enhanced Detection

**Motivation  
&  
Applications**

## Dr. Yanko Sheiretov

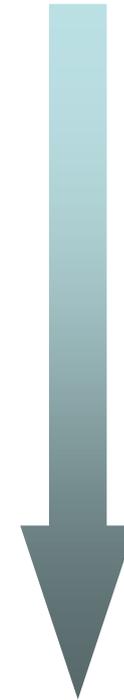
### Background on

- Sensor Model
  - Two-port Impedance Matrices, Transimpedance, Maxwell's Equations, Quasistatic Regimes, EM-field Partial Differential Equations and Solutions
- Multivariate Inverse Methods
  - Searching in multi-dimensional nonlinear spaces
  - Multi-dimensional nonlinear interpolation

**Physics  
&  
Details**

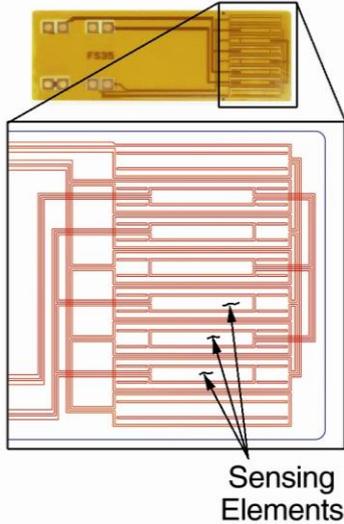
# Steps to Solving Challenging NDE Problems

- Sensor Design
- Calibration (*Standardization*)
- Measurement/Data Acquisition
- Multivariate Inverse Method
- Filters
- Decision Support Software

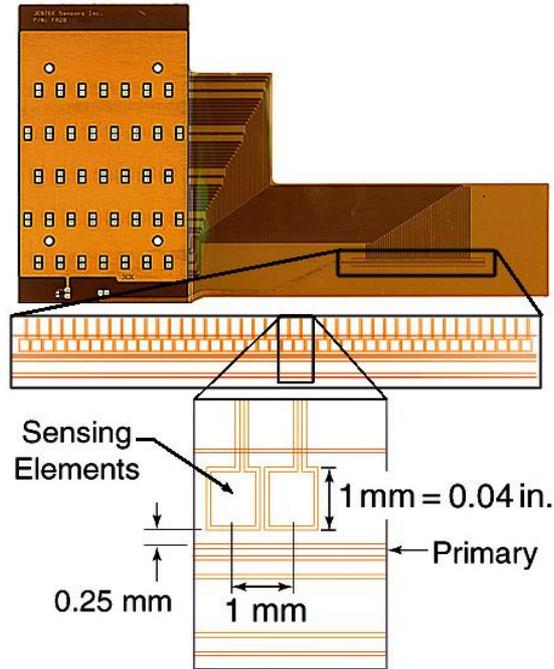


# MWM<sup>®</sup> & MWM-Array Eddy Current Sensors

Single-channel  
MWM sensor FS35



Multiple channel  
MWM-Array sensor FA28



Paradigm Shift  
*Design Sensors  
with rapid and  
accurate  
modeling as the  
primary focus*

Multiple channel  
MWM-Array FA106



# Air, Shunt Calibration (No Crack Standards) Now a U.S. Navy and Air Force Standard Practice

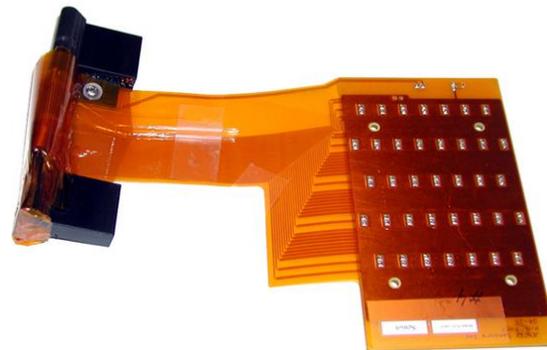
Sensor in “air”



Shunt Tip



Easy to Replace Cartridges:



- Sensor
- Shuttle
- Balloons

# 1993 Materials Evaluation Paper, Goldfine (Melcher)

## Multivariate Inverse Method using Pre-computed Measurement Grids

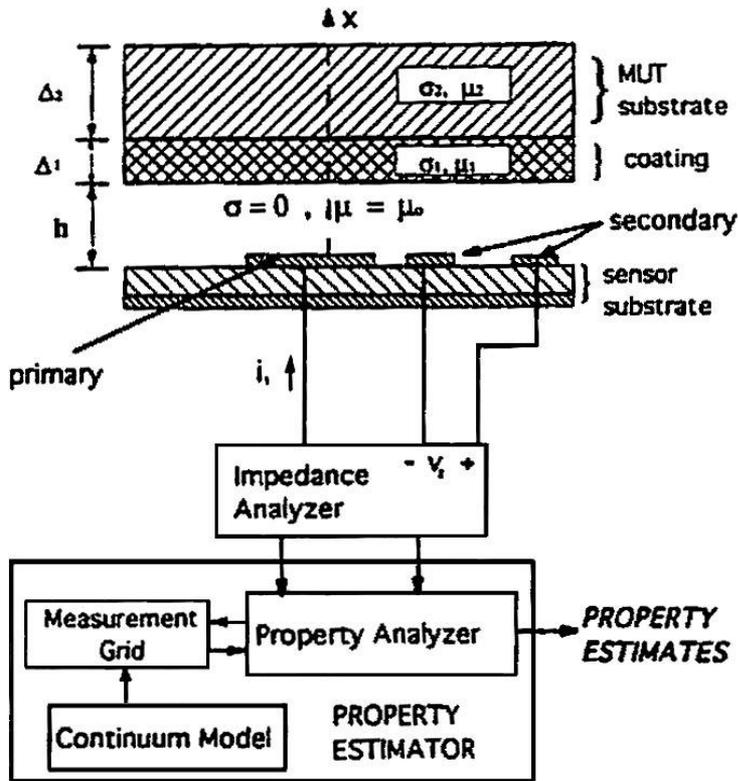


Figure 5—MWM prototype measurement system.

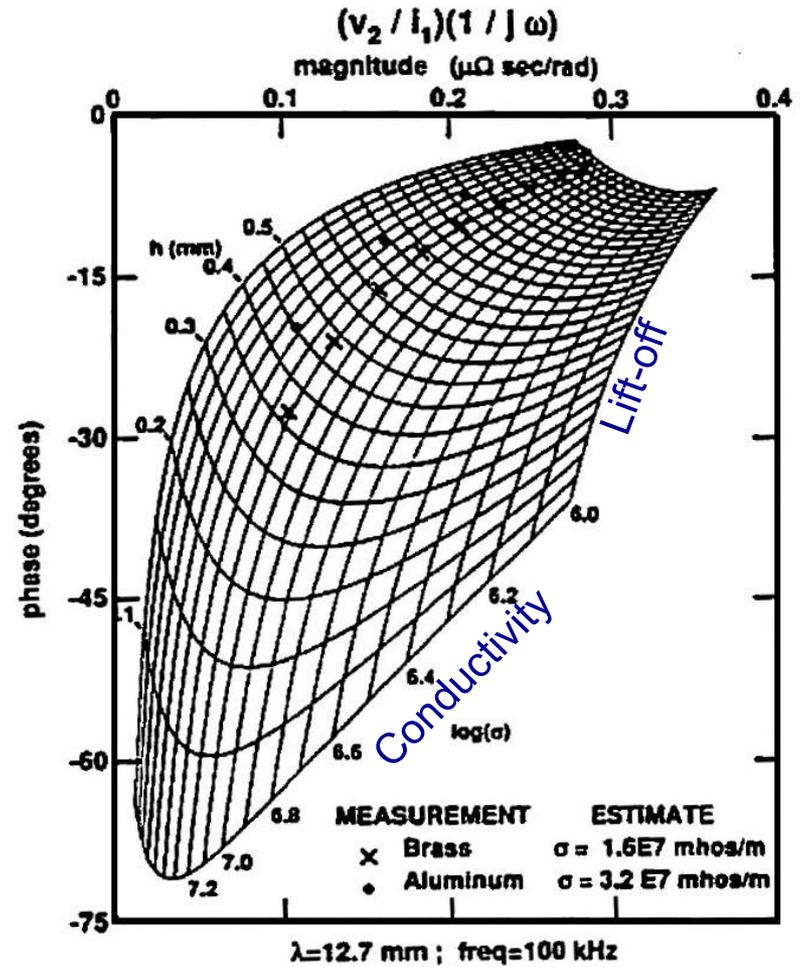


Figure 6—Property estimation grid for independent conductivity,  $\sigma$ , and liftoff,  $h$ , measurement ( $\lambda = 12.7 \text{ mm}$ ,  $f = 158 \text{ KHz}$ ).

# 1993 Materials Evaluation Paper, Goldfine (Melcher)

## Singular Value Decomposition for Measurement Procedure Development and Sensor Design

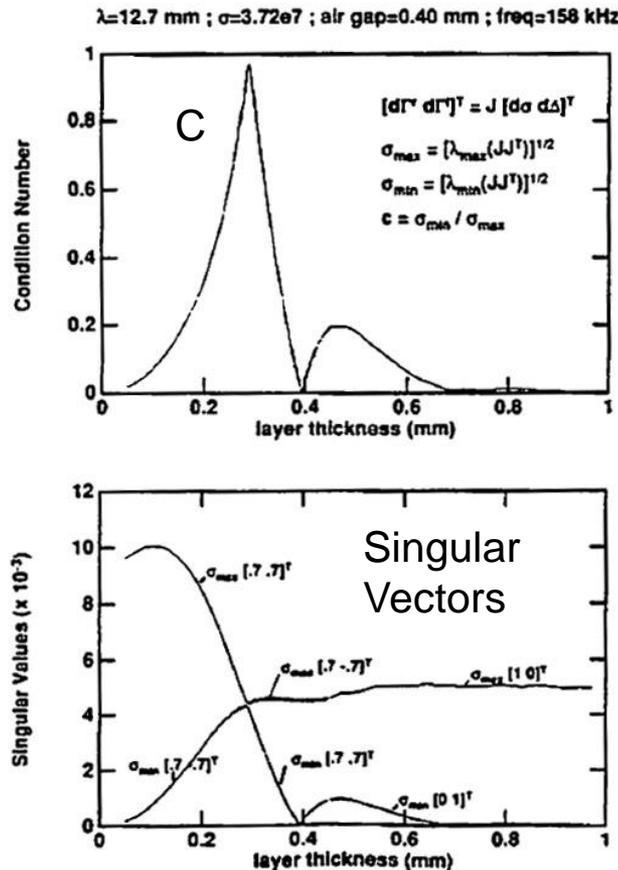
$$d\hat{\Gamma} = J d\theta$$

$$d\hat{\Gamma}_r = \frac{\partial \hat{\Gamma}_r}{\partial \sigma} d\sigma + \frac{\partial \hat{\Gamma}_r}{\partial \Delta} d\Delta$$

$$d\hat{\Gamma}_i = \frac{\partial \hat{\Gamma}_i}{\partial \sigma} d\sigma + \frac{\partial \hat{\Gamma}_i}{\partial \Delta} d\Delta$$

$$d\hat{\Gamma} = \begin{bmatrix} d\hat{\Gamma}_r \\ d\hat{\Gamma}_i \end{bmatrix}$$

$$d\theta = \begin{bmatrix} d\sigma \\ d\Delta \end{bmatrix}$$



$$[d\hat{\Gamma} \ d\hat{\Gamma}^T]^T = J [d\sigma \ d\Delta]^T$$

$$\sigma_{max} = [\lambda_{max}(JJ^T)]^{1/2}$$

$$\sigma_{min} = [\lambda_{min}(JJ^T)]^{1/2}$$

$$C = \sigma_{min} / \sigma_{max}$$

= Condition  
Number

= ratio of min/max  
singular values

Figure 10—Condition number  $C$ , maximum and minimum singular values,  $\sigma_{max}$ ,  $\sigma_{min}$ , and right-singular vectors of the jacobian,  $J$ , as a function of the coating thickness,  $\Delta$ , for an aluminum coating on an insulating substrate.

# 1993 Materials Evaluation Paper, Goldfine (Melcher)

## Singular Value Decomposition for Measurement Procedure Development and Sensor Design

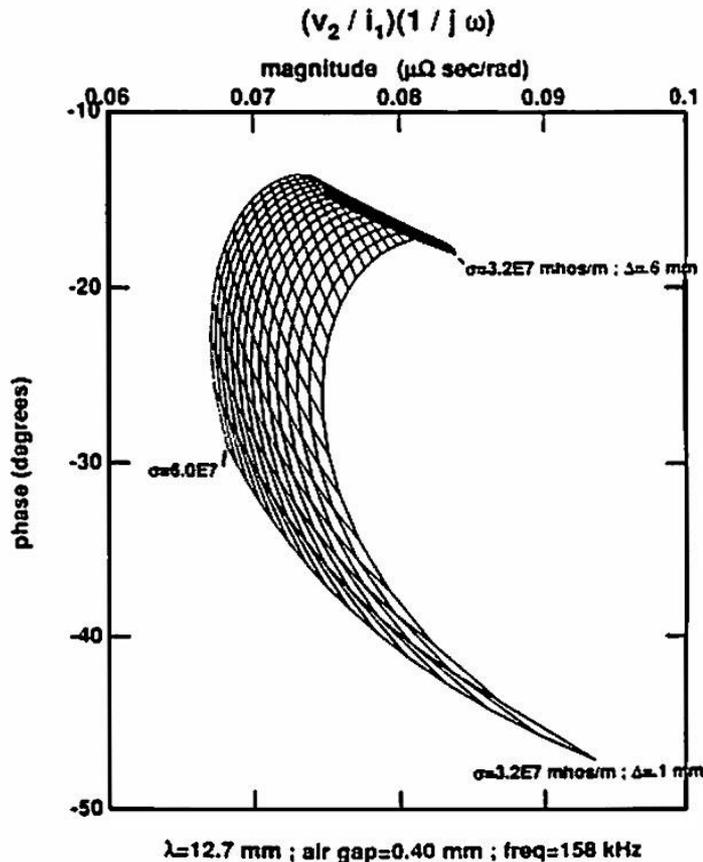


Figure 9—Property estimation grid for independent coating conductivity,  $\sigma$ , and thickness,  $\Delta$ , measurement ( $\lambda = 12.7$  mm,  $f = 158$  KHz,  $h = 0.4$  mm), for a metal coating on an insulating substrate.

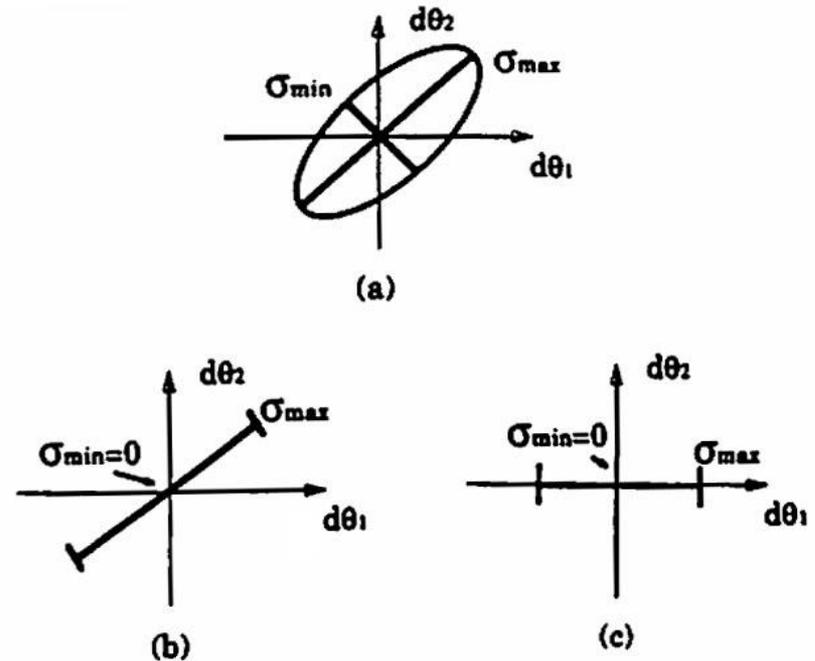


Figure 8—Generalized sensitivity ellipsoids for singular-value decomposition on a 2 by 2 Jacobian with unknown vector  $[d\theta_1, d\theta_2]^T$ : (a) example of good selectivity, (b) unobservable mode  $[0.7 \ -0.7]^T$ , and (c) unobservable mode  $[0 \ 1]^T$ .

# 1993 Materials Evaluation Paper, Goldfine (Melcher)

## Singular Value Decomposition for Measurement Procedure Development and Sensor Design

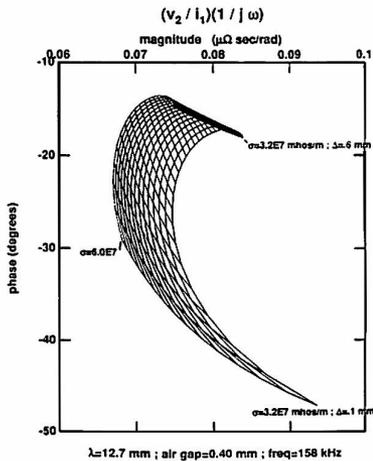


Figure 9—Property estimation grid for independent coating conductivity,  $\sigma$ , and thickness,  $\Delta$ , measurement ( $\lambda = 12.7$  mm,  $f = 158$  KHz,  $h = 0.4$  mm), for a metal coating on an insulating substrate.

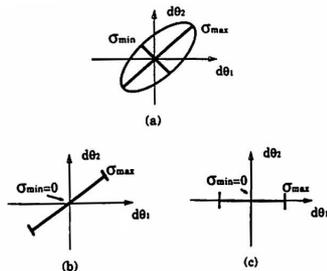


Figure 8—Generalized sensitivity ellipsoids for singular-value decomposition on a 2 by 2 Jacobian with unknown vector  $(\delta_1, \delta_2)^T$ : (a) example of good selectivity, (b) unobservable mode  $[0.7 \ 0.7]^T$ , and (c) unobservable mode  $[0 \ 1]^T$ .

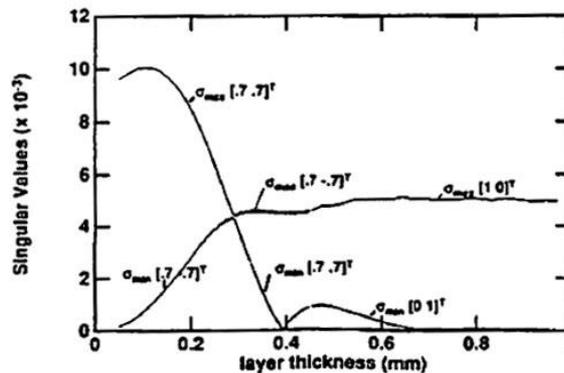
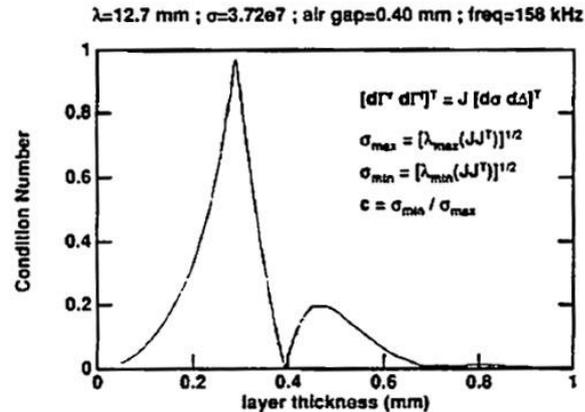


Figure 10—Condition number  $C$ , maximum and minimum singular values,  $\sigma_{max}$ ,  $\sigma_{min}$ , and right-singular vectors of the Jacobian,  $J$ , as a function of the coating thickness,  $\Delta$ , for an aluminum coating on an insulating substrate.

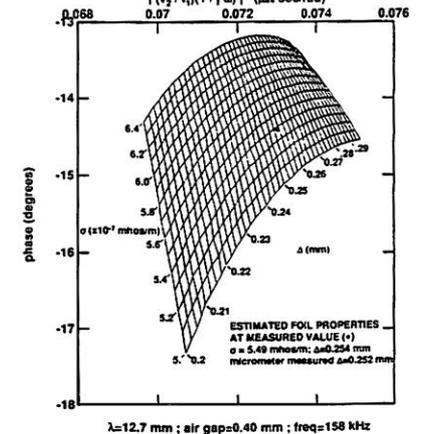
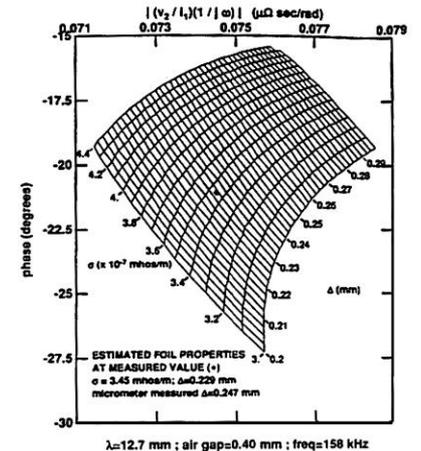


Figure 11—Magnified property estimation grid for independent conductivity and thickness measurement for (a) aluminum coatings and (b) copper coatings with thickness between 0.2 mm and 0.3 mm, on insulating substrates. Actual transinductance magnitude and phase are plotted for an aluminum and copper coating conductivity and thickness measurement.



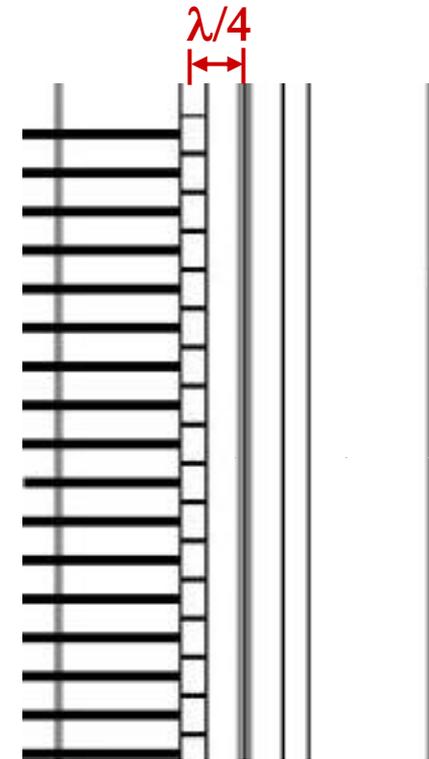
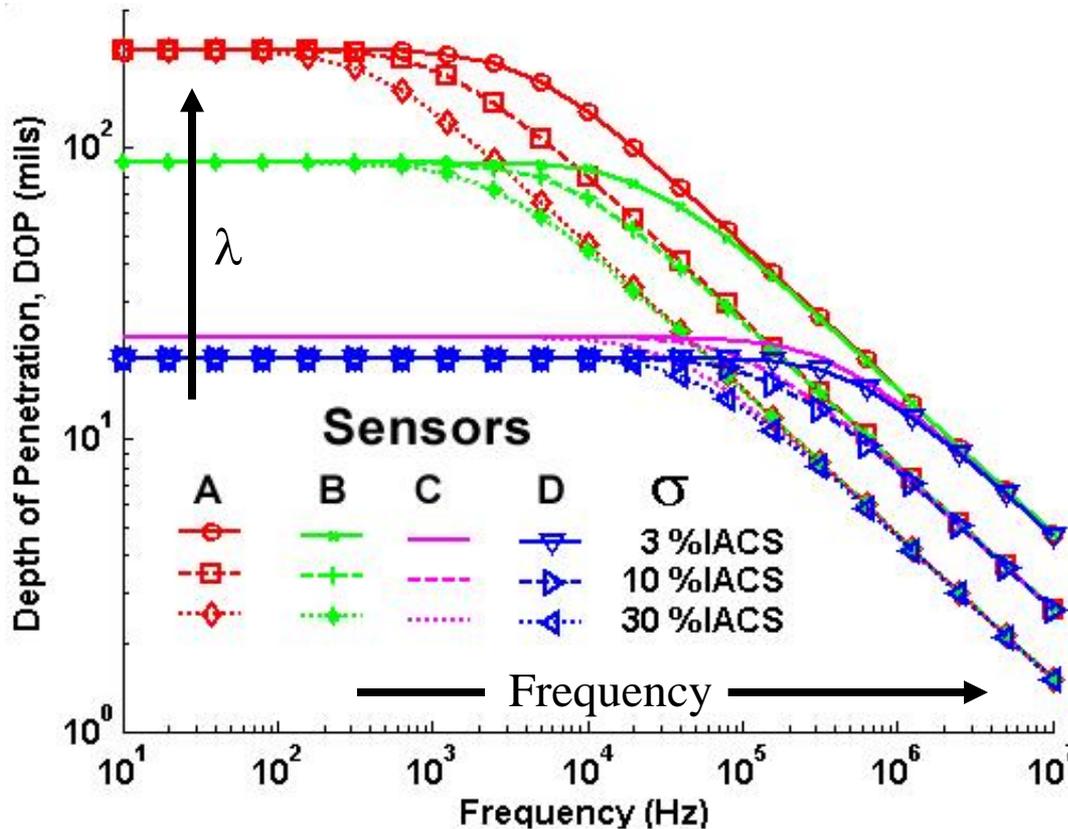
# Depth of Penetration for MWM Sensors and MWM-Arrays

Field Variation with Depth  $\propto e^{-\Gamma_n z}$

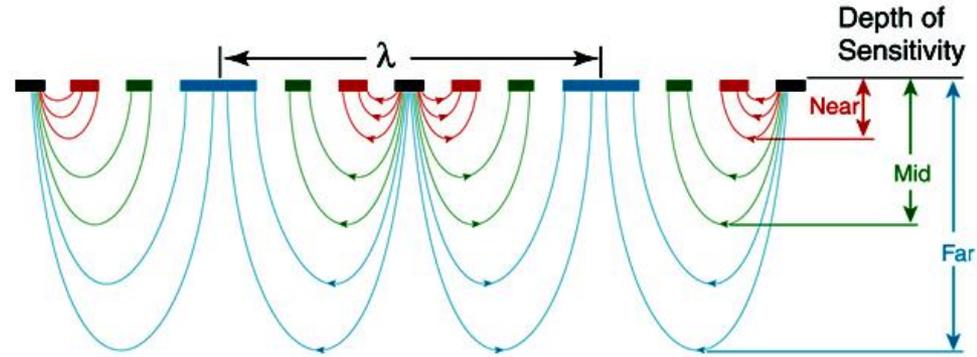
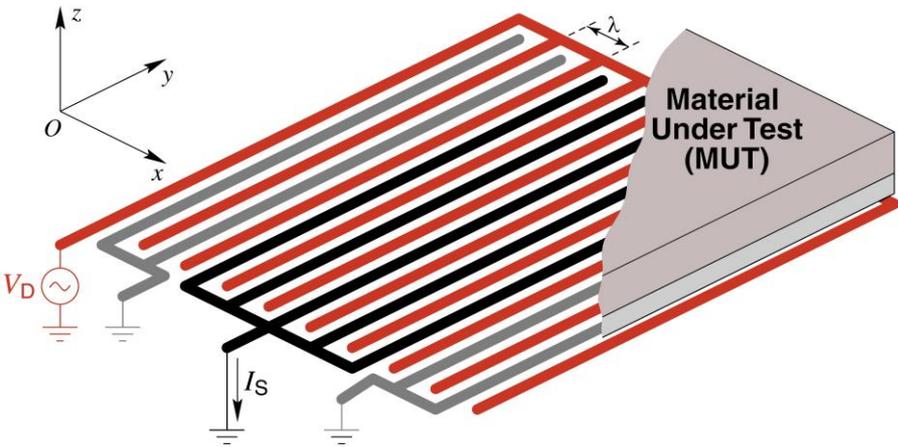
Spatial Fourier Mode Depth of Penetration =  $1/\Re(\Gamma_n)$

$$\Gamma_n = \sqrt{(2\pi n/\lambda)^2 + 2j/\delta^2}$$

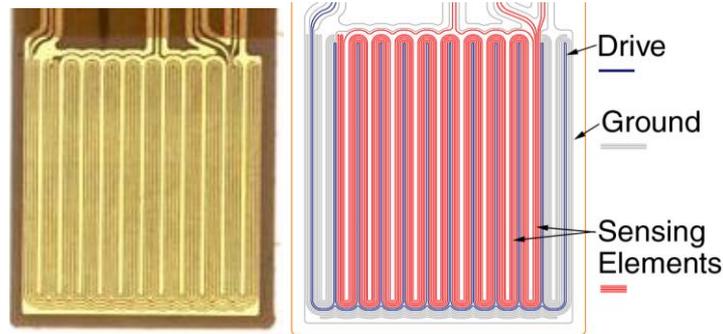
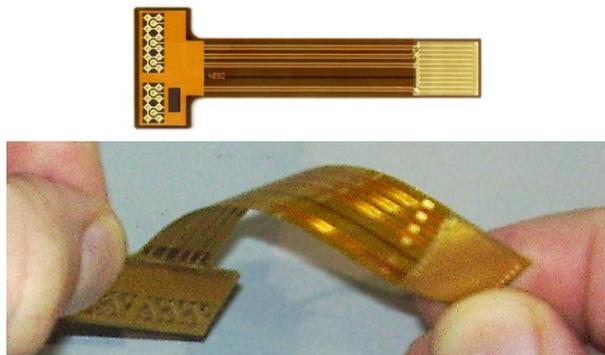
Skin depth:  $\delta = \sqrt{1/(\pi f \mu \sigma)}$



# Interdigitated Electrode (IDED<sup>®</sup>) Dielectrometer



Three-wavelength co-located segmented-field dielectrometer

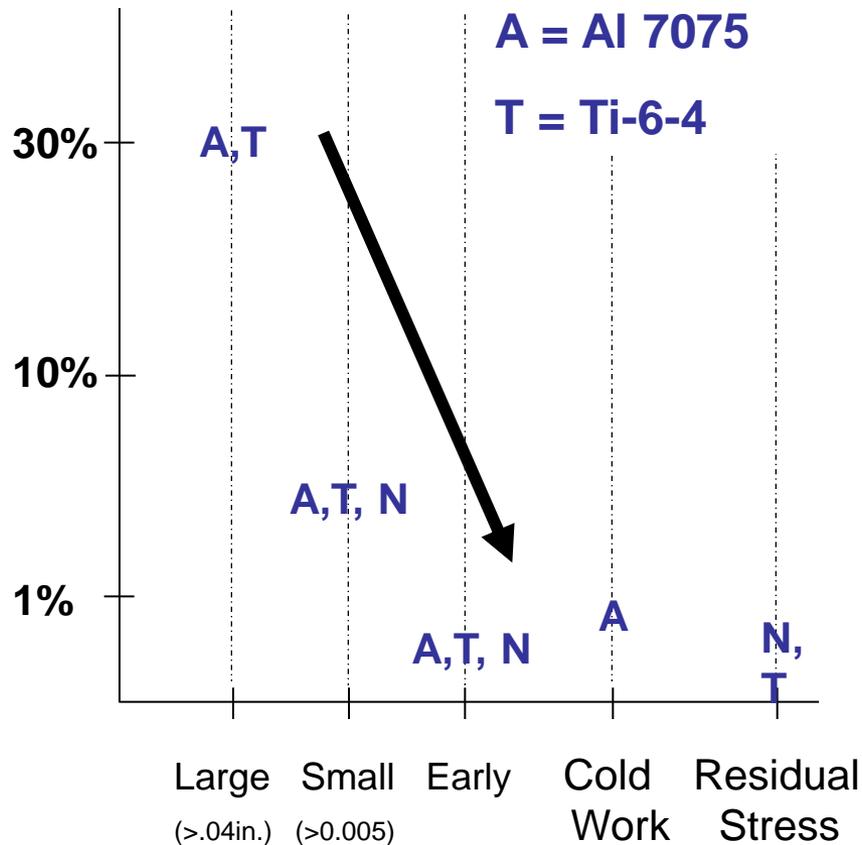


# Example Applications

- Conductivity Imaging for Cracks and Residual Stresses
- Coating Characterization
- Non-Contact Torque, Axial and Bending loads

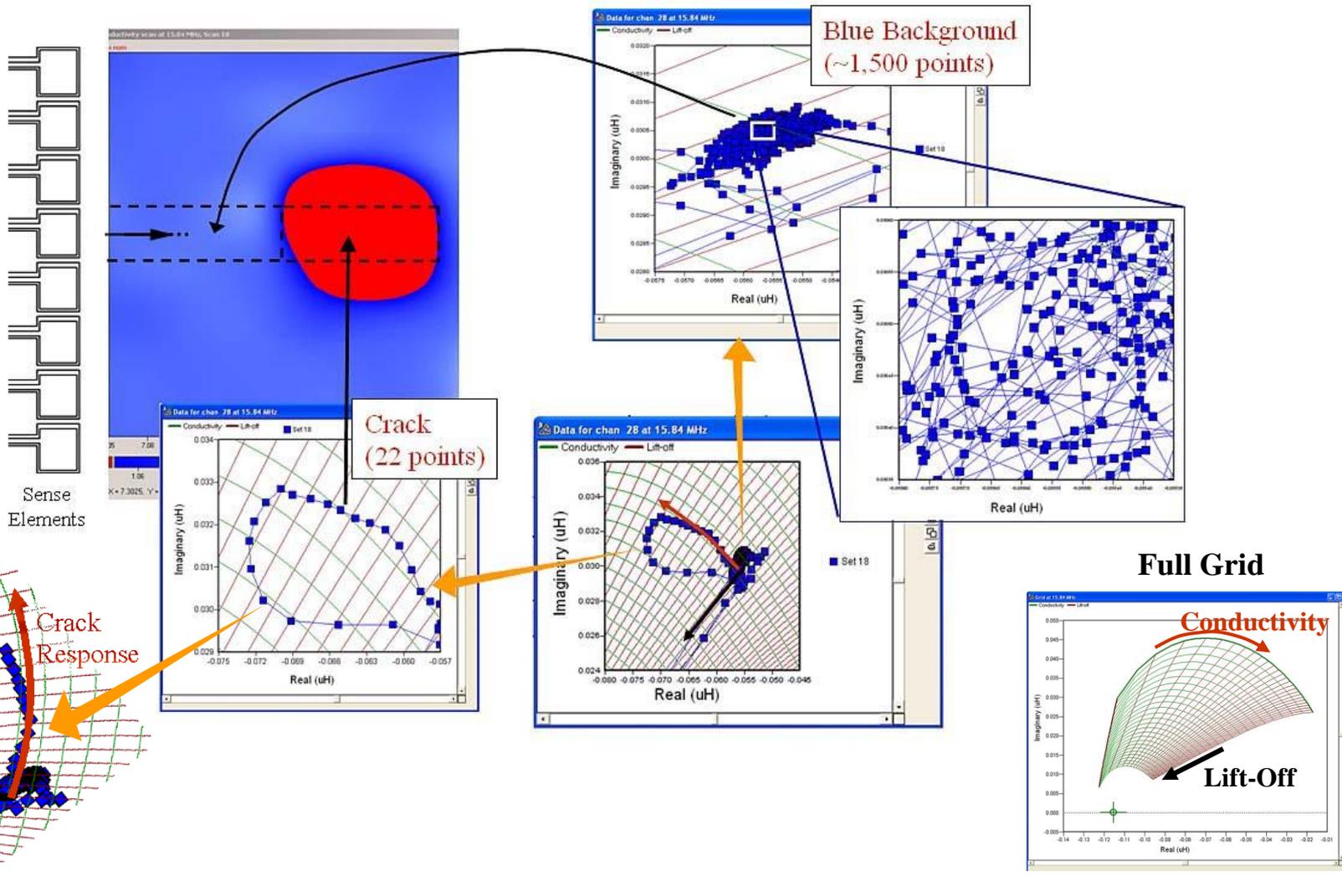
# MWM-Array Conductivity Imaging History

**% Absolute Conductivity Change\***



Application	MWM-Array Measured Conductivity Change*	
	Al	Ti Ni
“Large Cracks” Length > 0.03in.	> 8%	>8%
“Small” Cracks Length >0.005 in.	1-8%	1-8%
Early Fatigue (micro-cracks)	<1%	<1%
Cold work	~1%	N/A
Residual Stress	N/A	<0.3%, <1%

# Rapid Data Processing with Grid Methods and "Air" Calibration

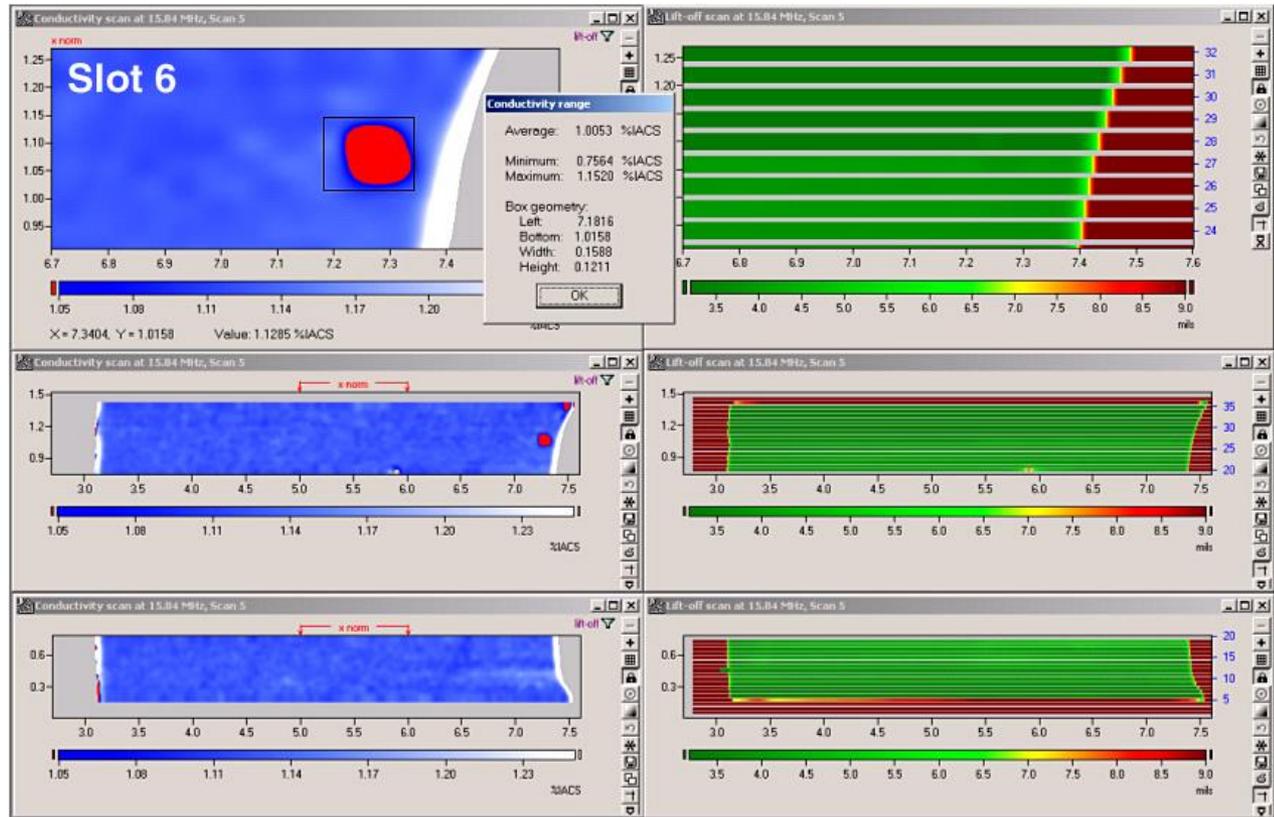


# Automated Engine Disk Slot Inspection System

- In use at NAVAIR Depot since April 2005
- Disks with verified cracks detected, several of these large and small cracks **not detected by conventional ET and LPT**
- Low False Alarm Rate

Conductivity

Lift-Off



MWM-Array  
Probe

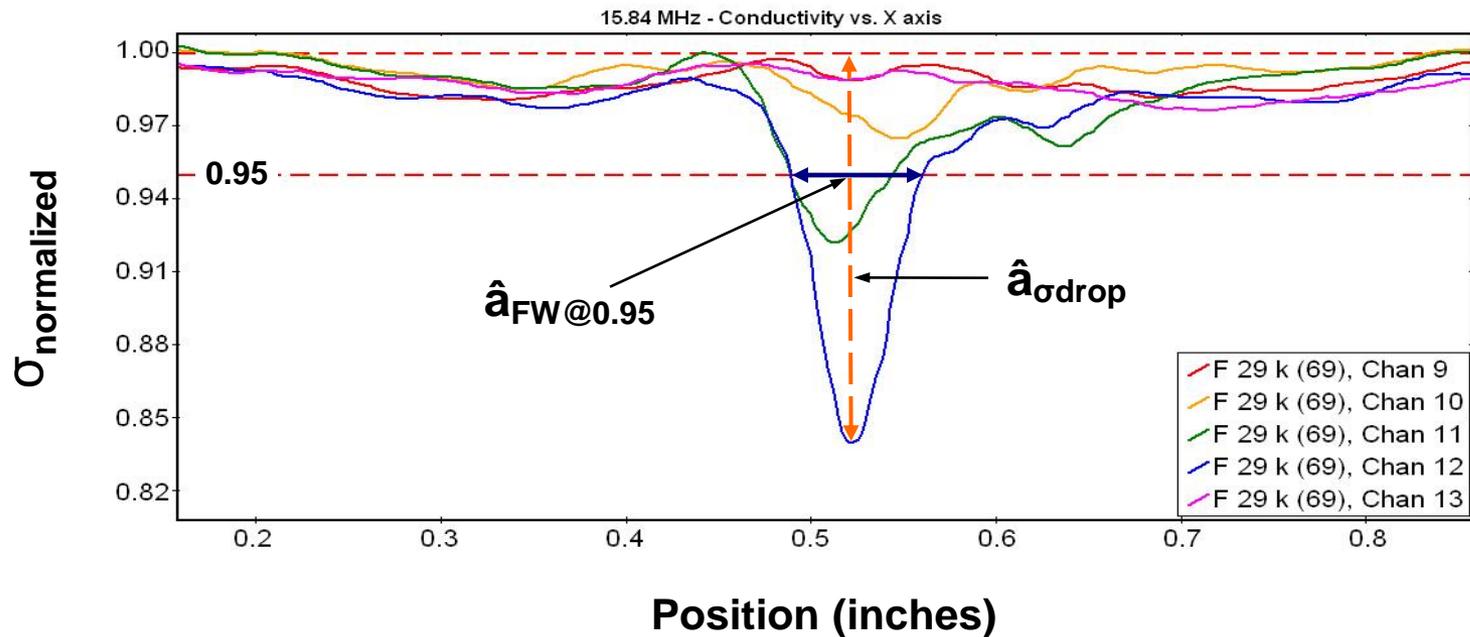
MWM-Array  
Sensor

# â Definitions

$\hat{a}_{\sigma\text{drop}}$  VS  $\hat{a}_{\text{FW}@0.95}$



## Coupon Fatigue Crack Response (16.9 mils)



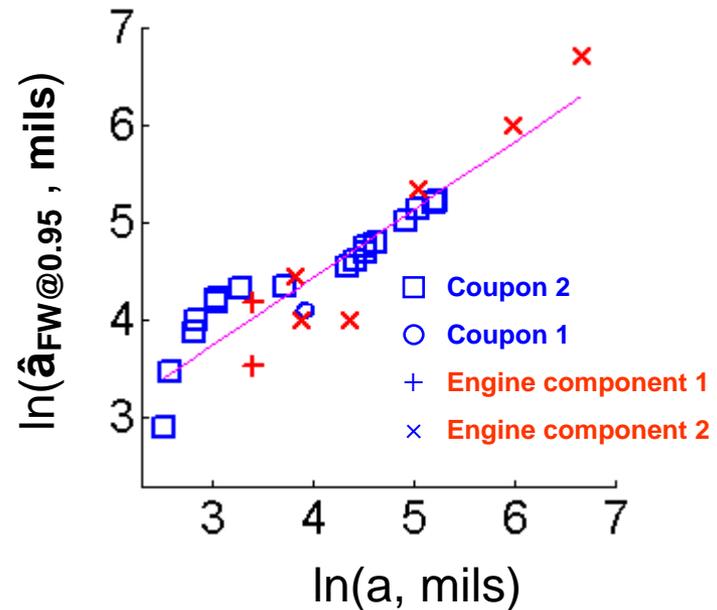
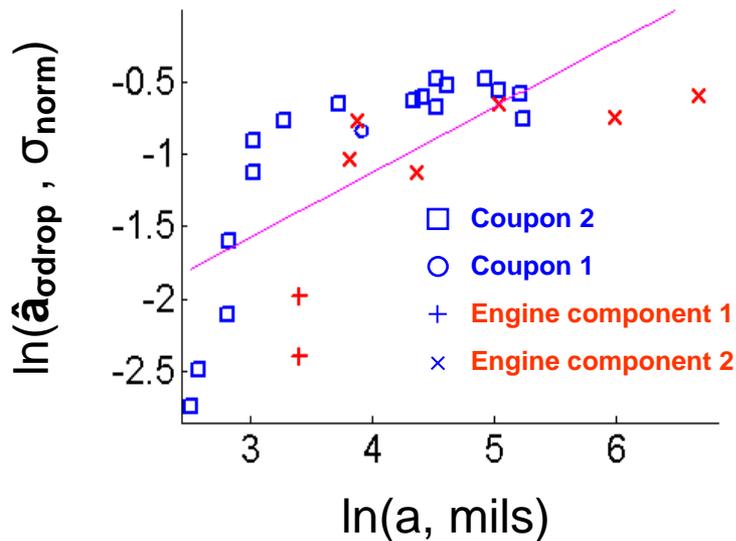
# $\hat{a}$ vs $a$ Plots

$\hat{a}_{\text{odrop}}$  VS  $\hat{a}_{\text{FW@0.95}}$



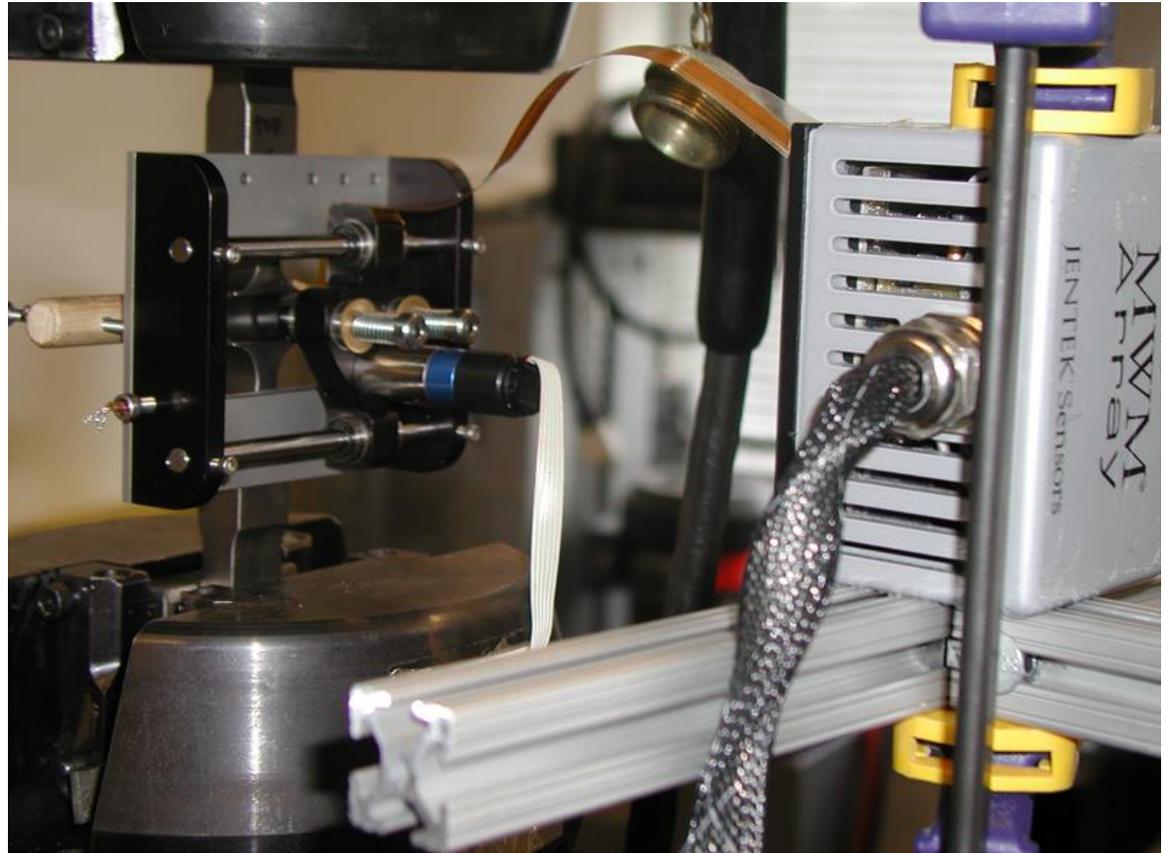
Log( $\hat{a}_{\text{odrop}}$ ) vs log( $a$ ) regression

Log( $\hat{a}_{\text{FW@0.95}}$ ) vs log( $a$ ) regression



**Note:** Above a 0.04 in. crack length the  $\hat{a}_{\text{FW@0.95}}$  definition produces an “unbiased estimator” for crack length. Below 0.02 in. crack lengths multiple small cracks result in a positively biased crack length estimate.

# Fatigue Specimen and Test Setup (7-Channel FA43)



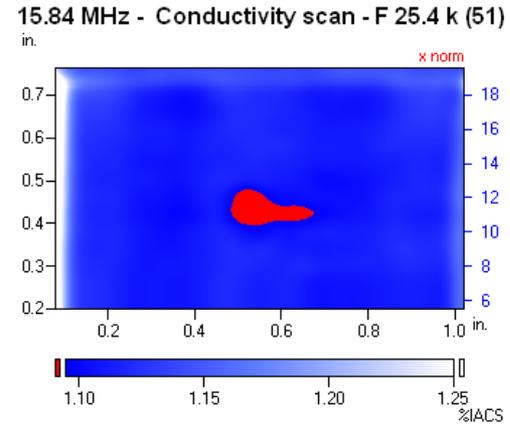
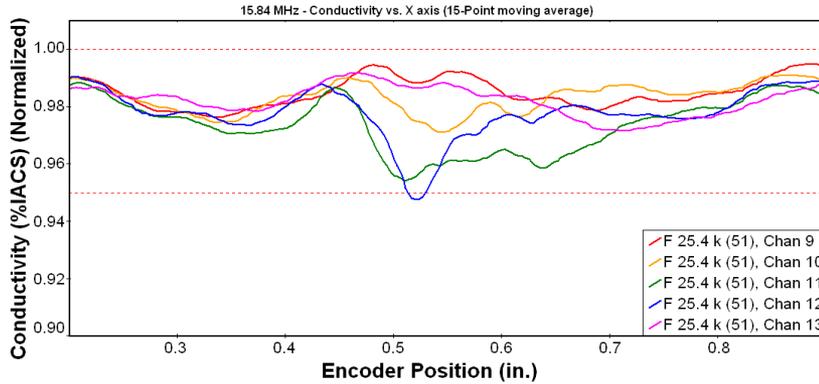
**MWM-Array FA43**

## Coupon Example Cracks

Interval	Total Cycles	a, mils
0	0	0
2	6,000	3.9
11	27,376	16.7
12	29,041	16.9
25	41,000	186.6

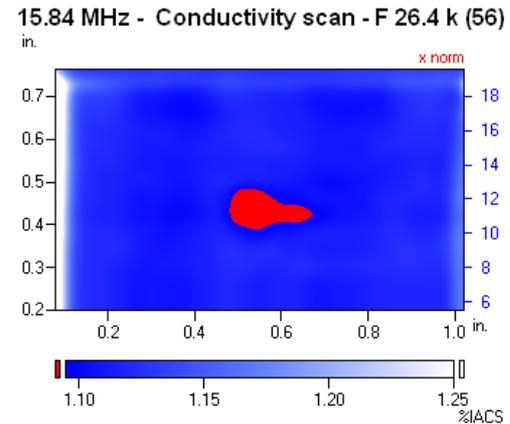
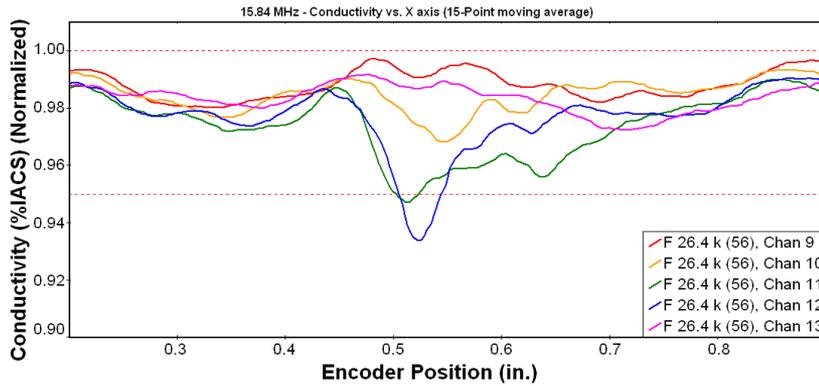
**37-Channel  
MWM-Array  
FA57**

**25,376  
Cycles**



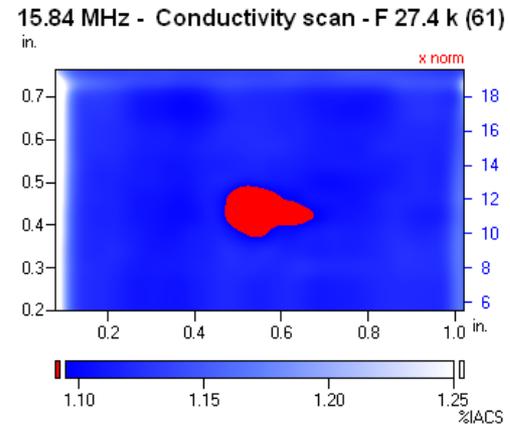
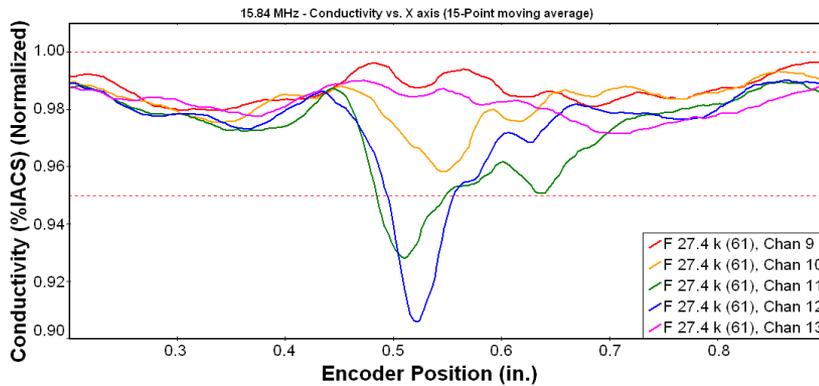
**Crack  
12.3 mils**

**26,376  
Cycles**



**Crack  
13.2 mils**

**27,376  
Cycles**



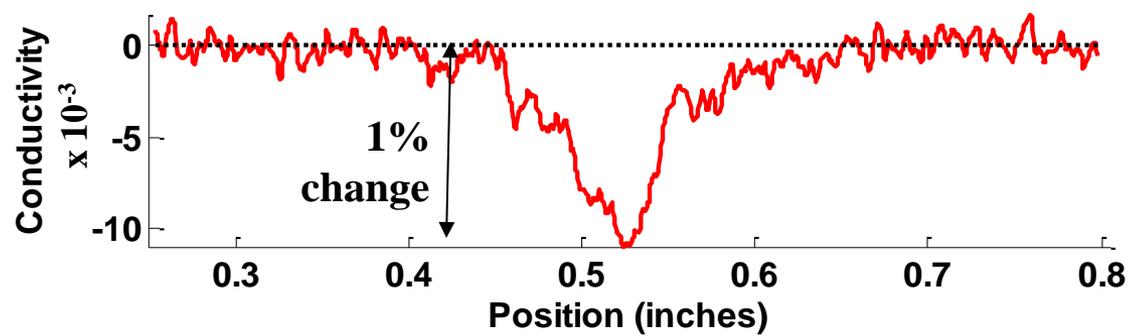
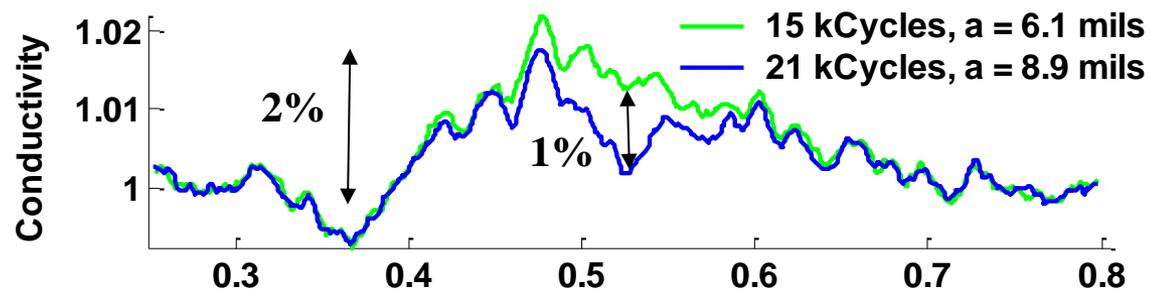
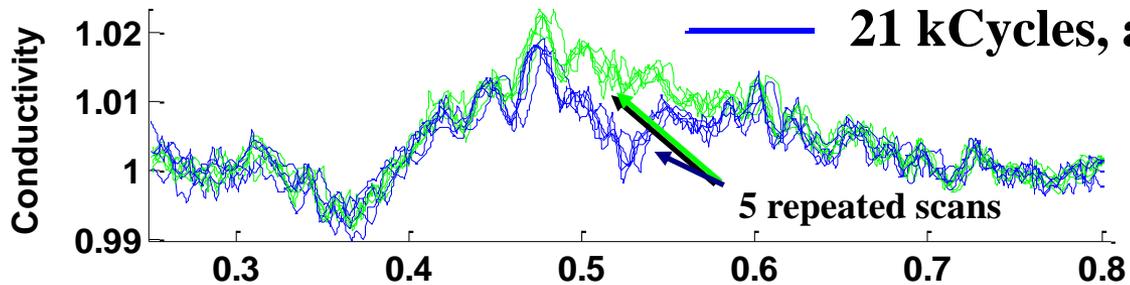
**Crack  
16.7 mils**

# Difference Imaging Provides Improved Sensitivity, with Averaging of 5 Repeat Scans Reduces Noise

Channel 12

Crack Length

— 15 kCycles, a = 6.1 mils } **2.8 mil growth**  
— 21 kCycles, a = 8.9 mils } **in crack length**

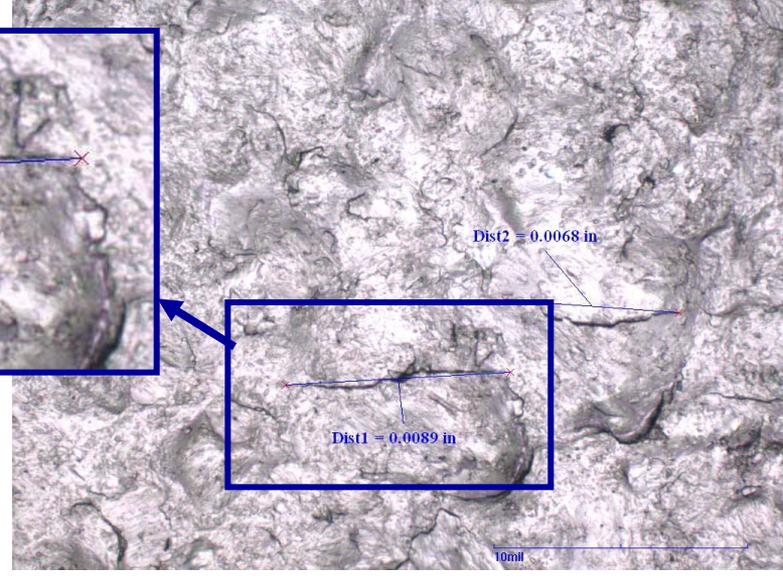
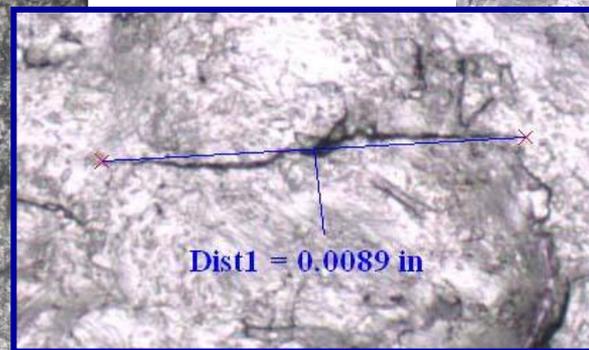
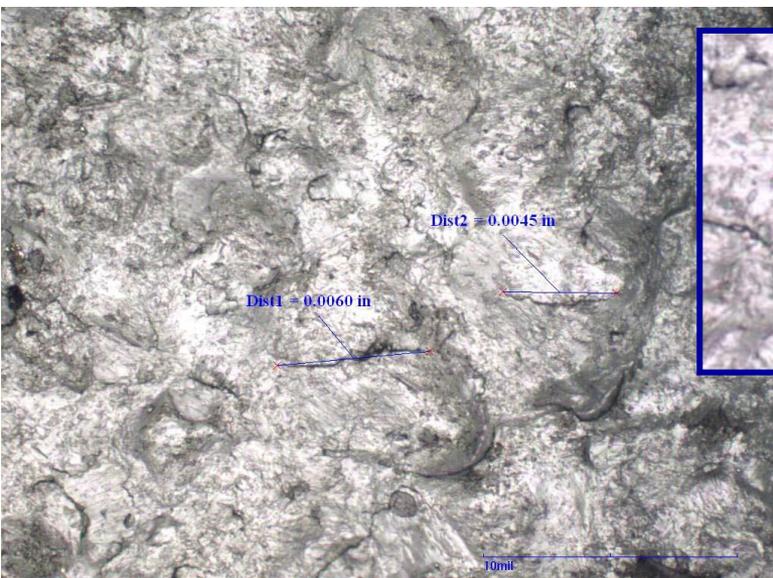
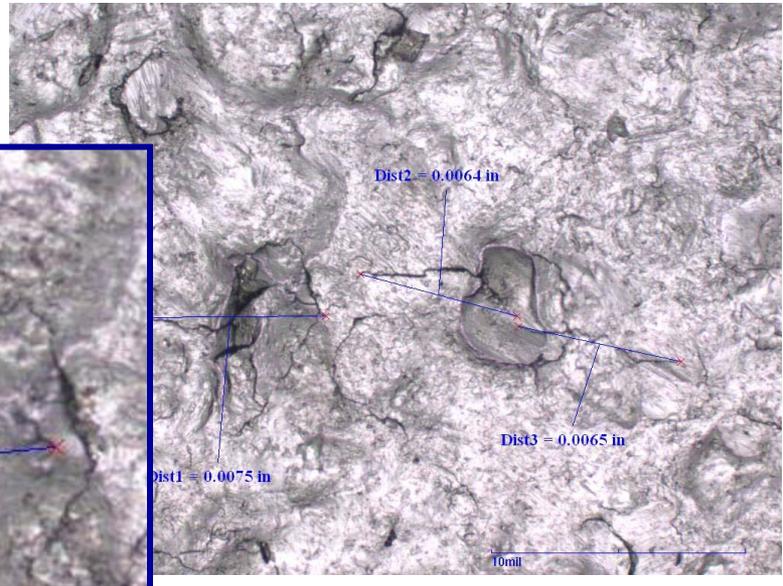
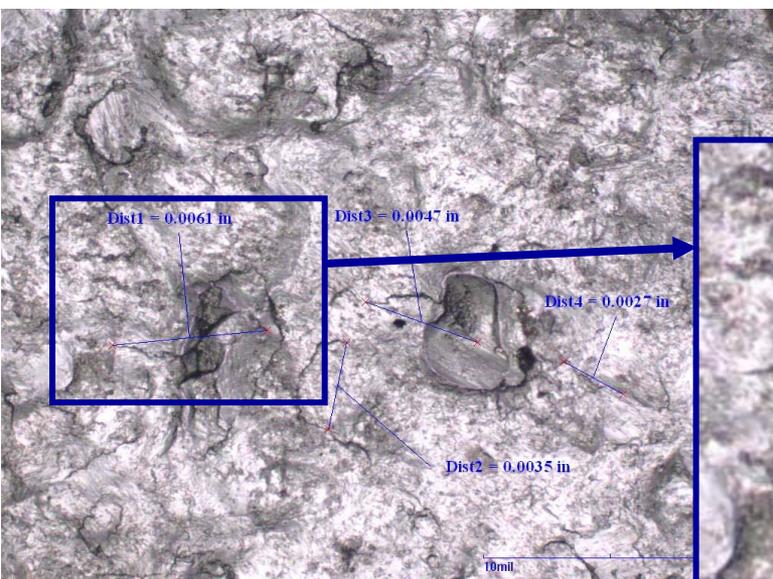


Average of  
5 repeated  
scans

Difference

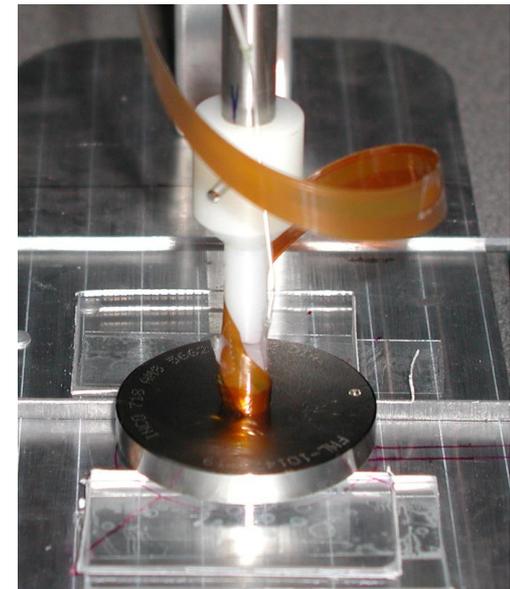
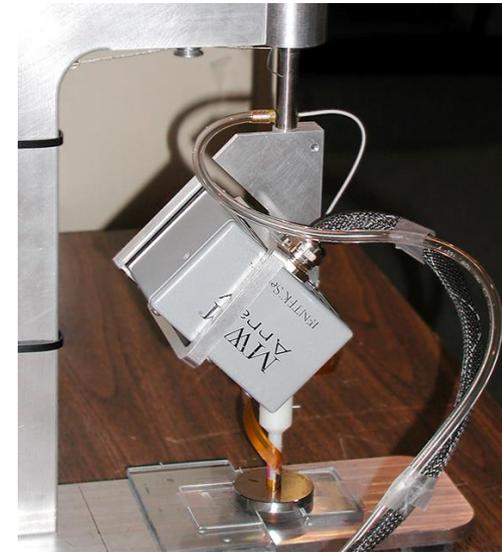
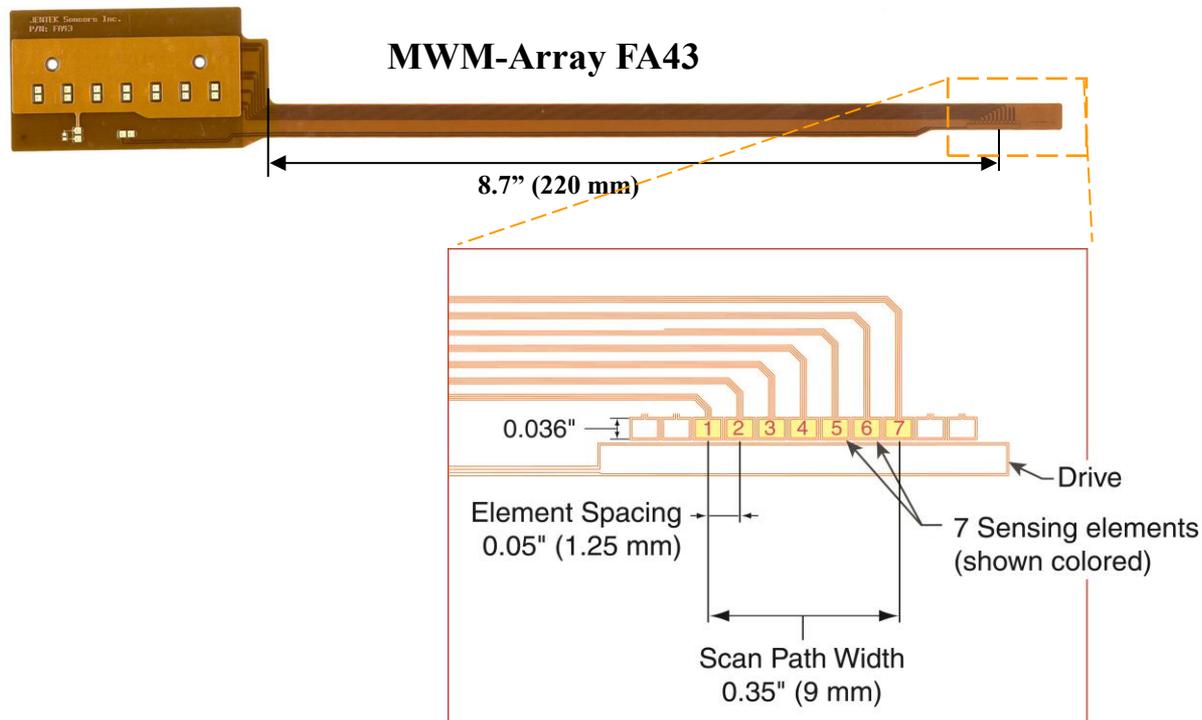
# 15 kCycles, a = 6.1 mils

# 21 kCycles, a = 8.9 mils



# Bolt Hole Inspection

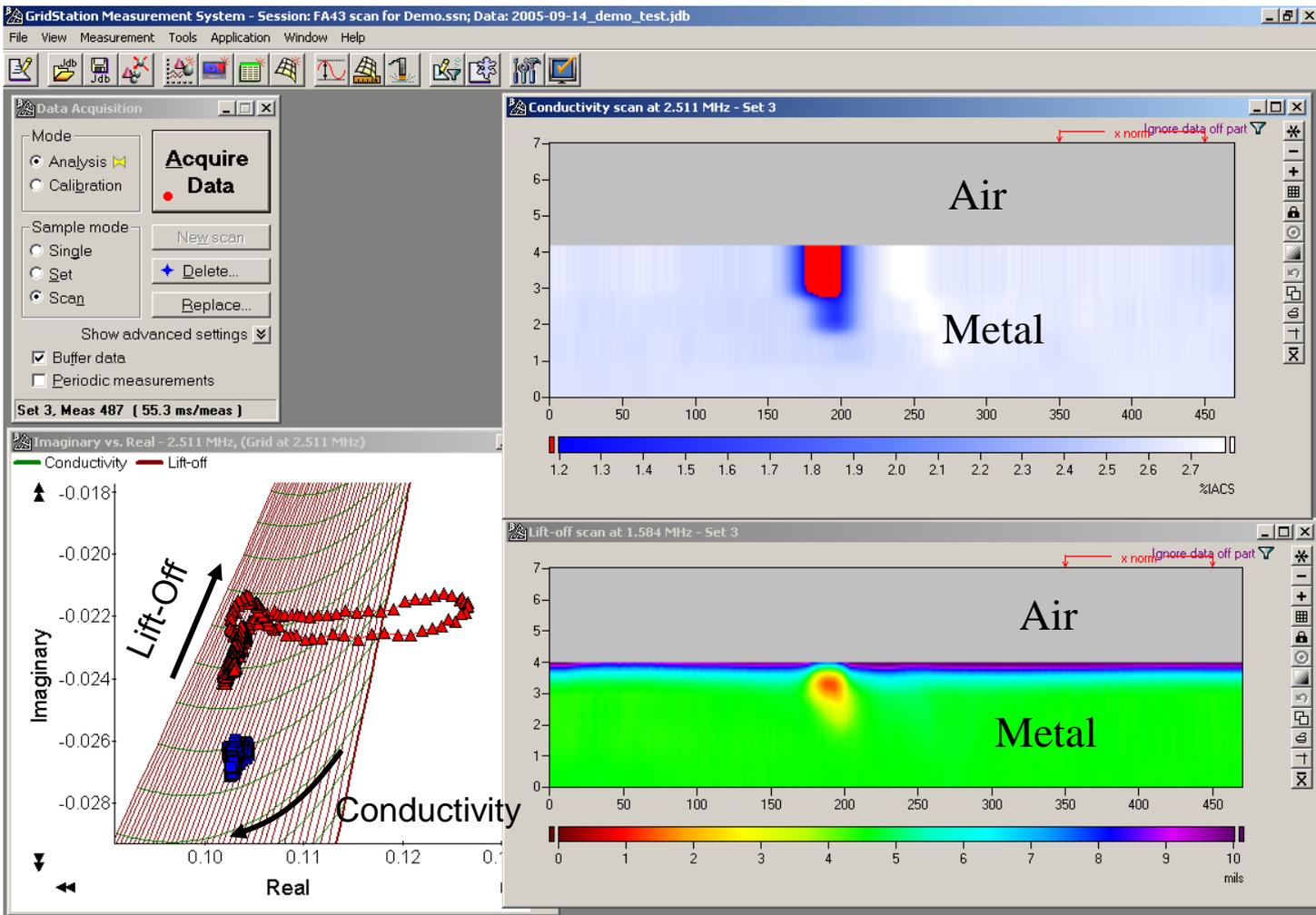
- C-Scan Imaging using MWM-Arrays
- Detection of Cracks at Edges with edge location correction
- Spatial Filtering for Cracks at Edges



# Bolt Hole Inspection

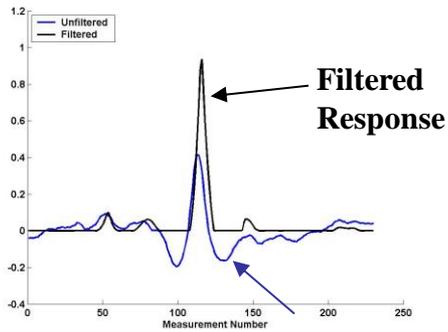
## Detection of Cracks at Edges with Edge Location Correction

### GridStation Conductivity/Lift-Off Images (Unfiltered)

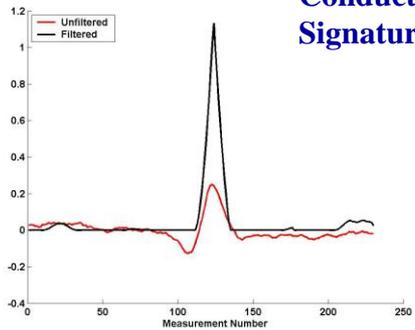


# Detection of Cracks at Edges with:

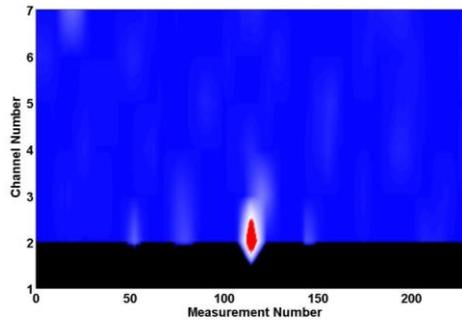
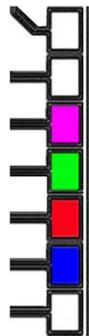
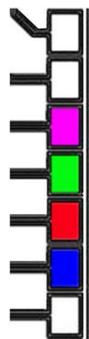
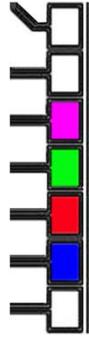
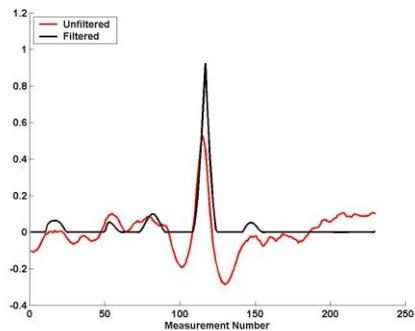
- Edge location correction, and
- Spatial Filtering, using Signature Libraries



Filtered Response

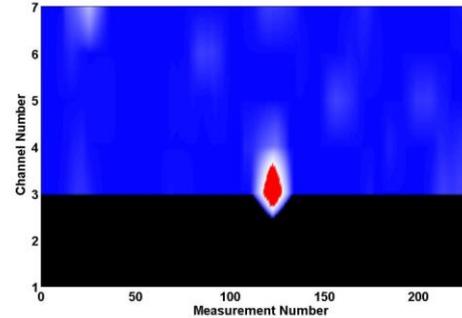
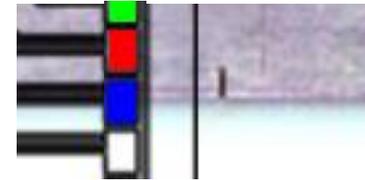


Conductivity Signature

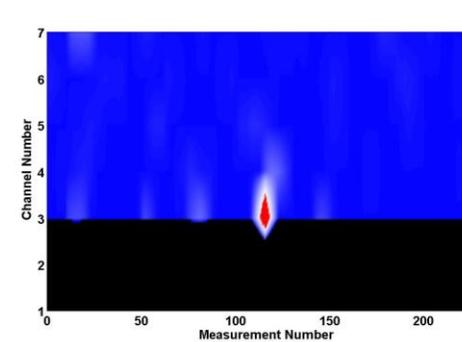
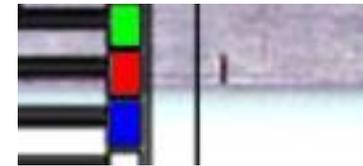


0.30 in.

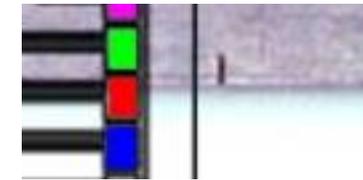
Channel 2, Lift-Off Factor = -0.69



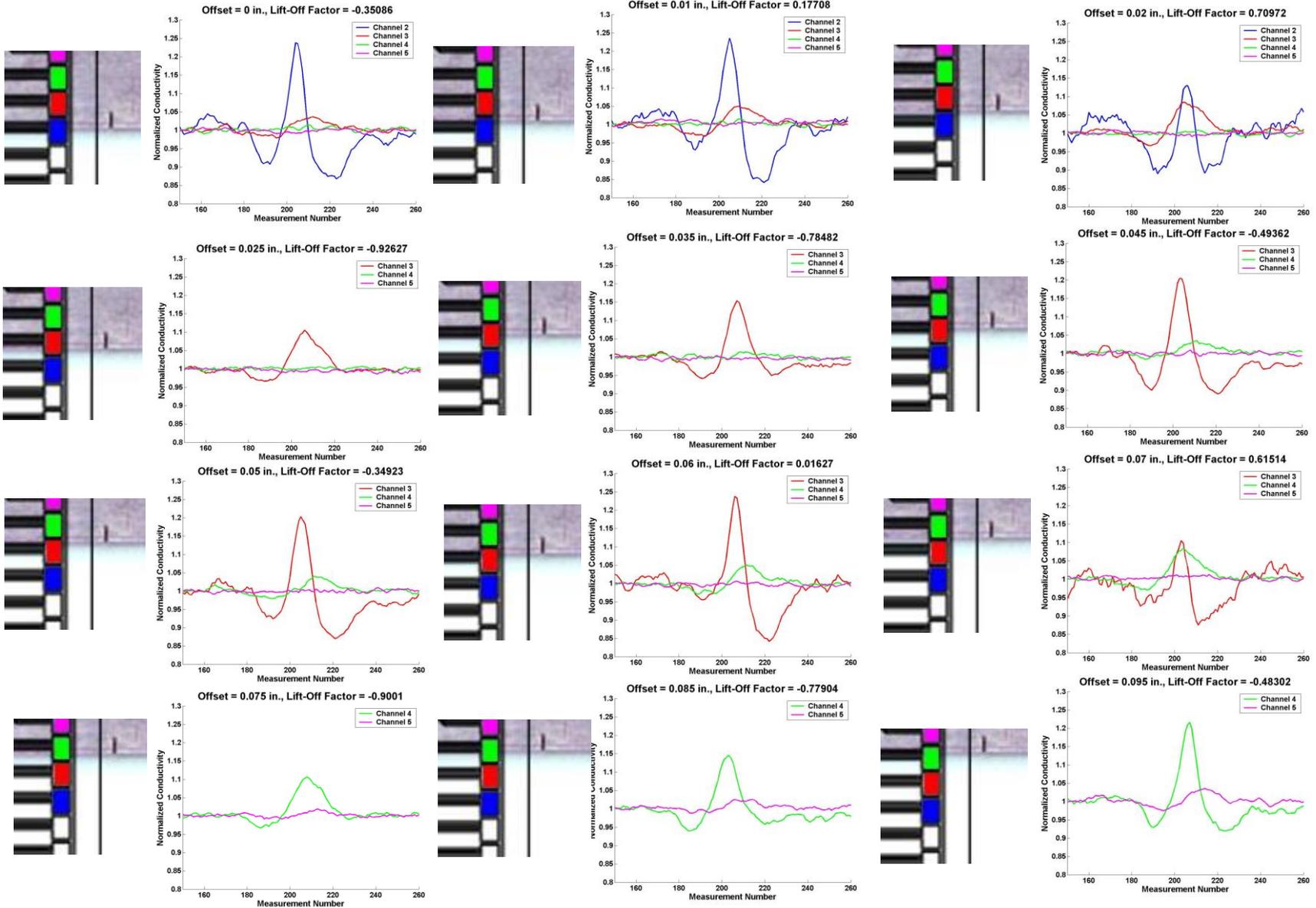
Channel 3, Lift-Off Factor = -0.96



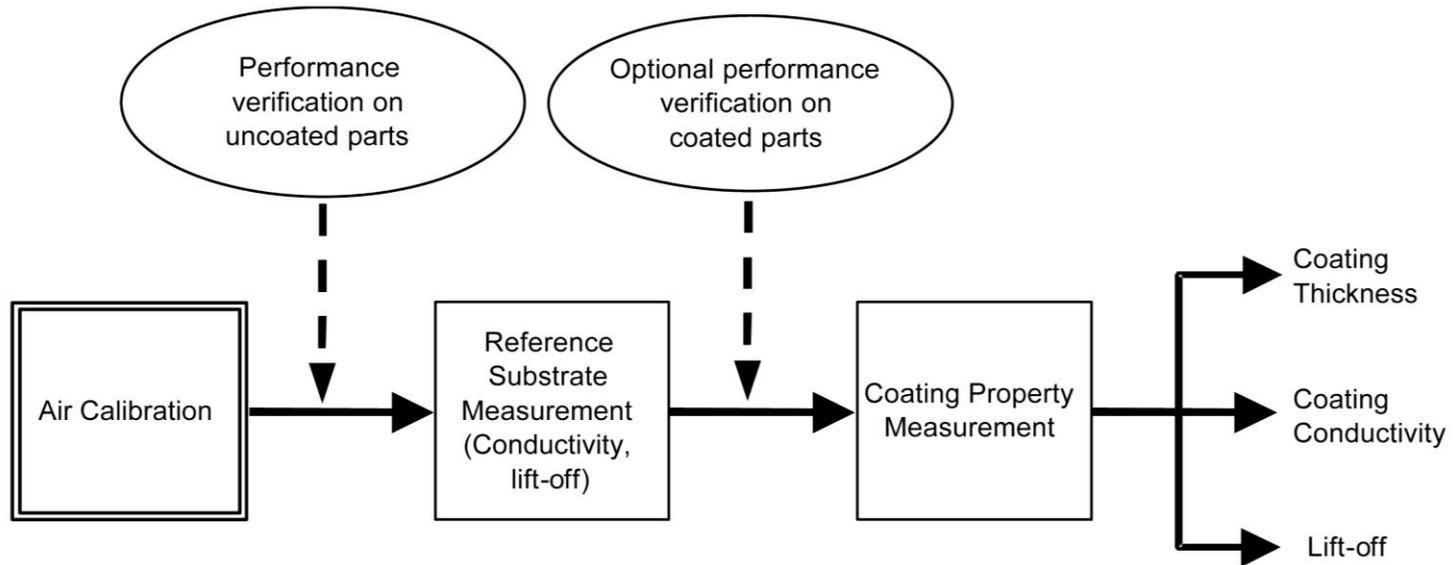
Channel 3, Lift-Off Factor = -0.47



# Signature Library



# ASTM Standard – “Air Calibration”



Designation: E 2338 – 04

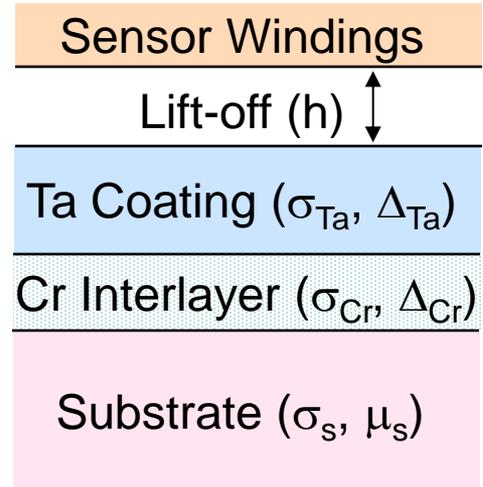
## Standard Practice for Characterization of Coatings Using Conformable Eddy- Current Sensors without Coating Reference Standards<sup>1</sup>

This standard is issued under the fixed designation E 2338; the number immediately following the designation indicates the year of original adoption or, in the case of revision, the year of last revision. A number in parentheses indicates the year of last reapproval. A superscript epsilon ( $\epsilon$ ) indicates an editorial change since the last revision or reapproval.

# HyperLattices

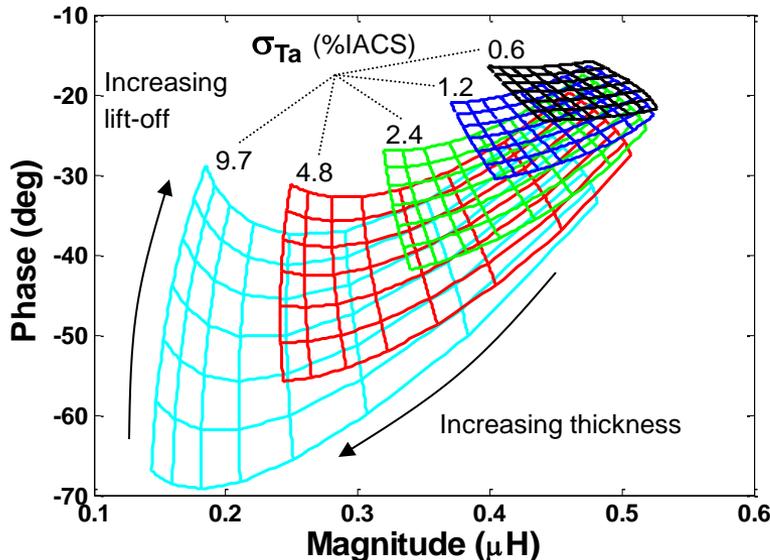
(patents issued and pending)

- Measure Four Unknowns
- Provide High Resolution image of each unknown
- Automated & Real-Time



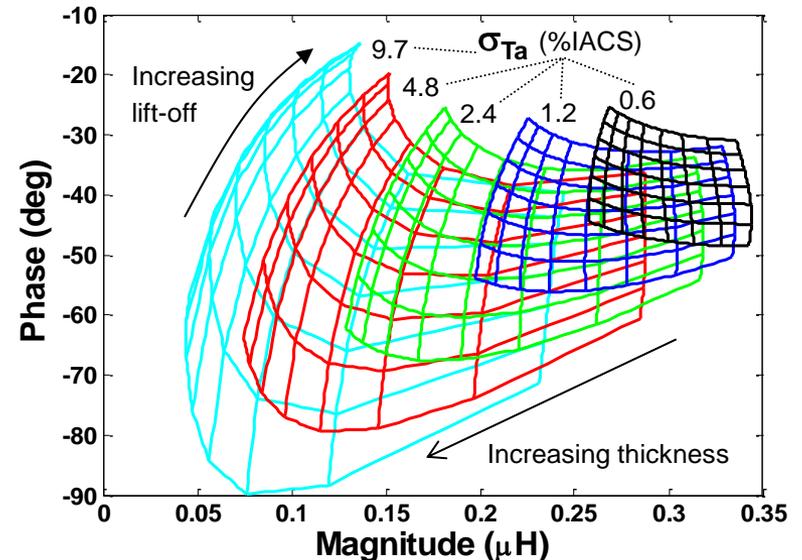
### Low $f$ $\sigma_{Ta}$ - $\Delta_{Ta}$ -h Lattice

$\mu_s$ ,  $\sigma_s$ ,  $\sigma_{Cr}$ ,  $\delta_{Cr}$  constant

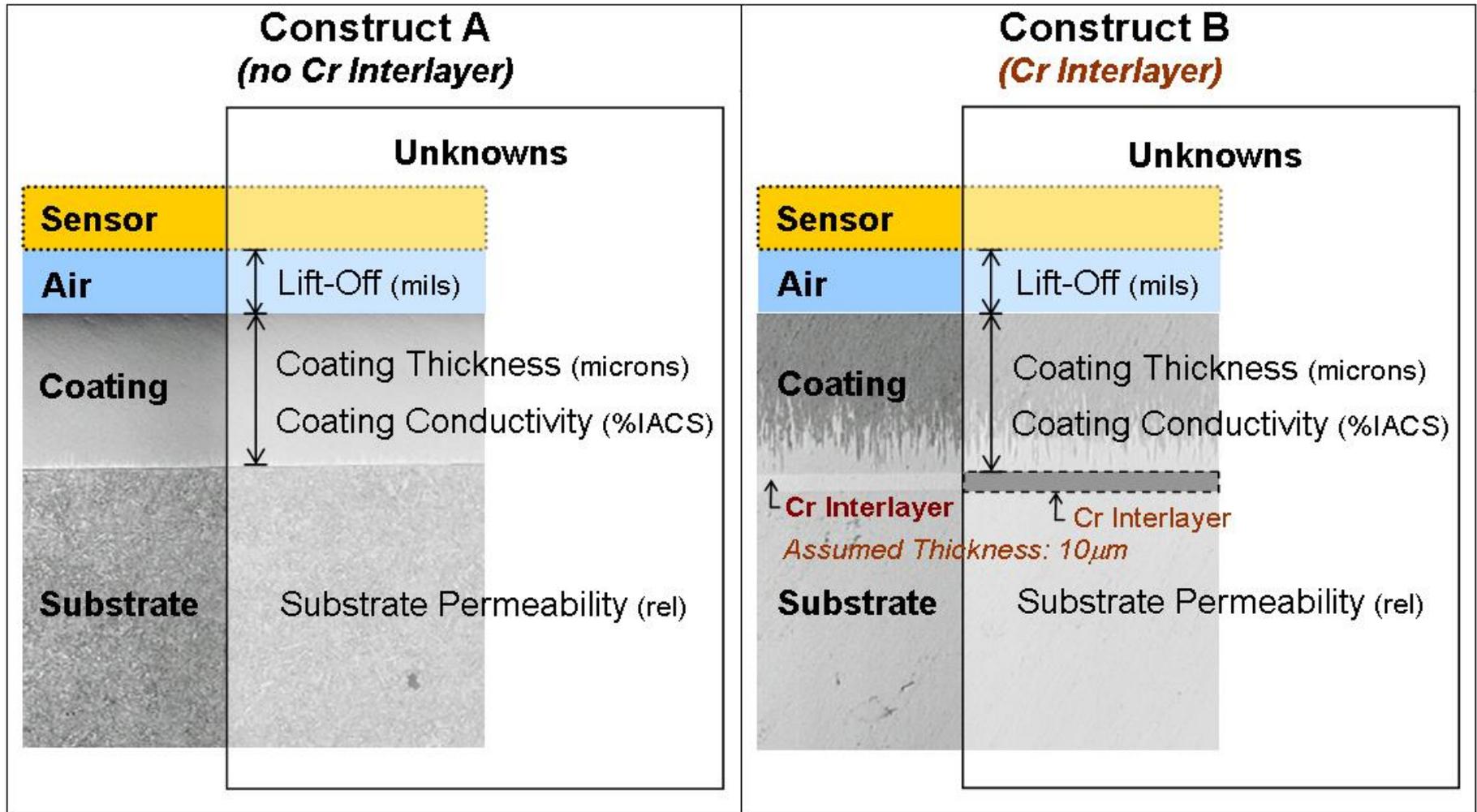


### High $f$ $\sigma_{Ta}$ - $\Delta_{Ta}$ -h Lattice

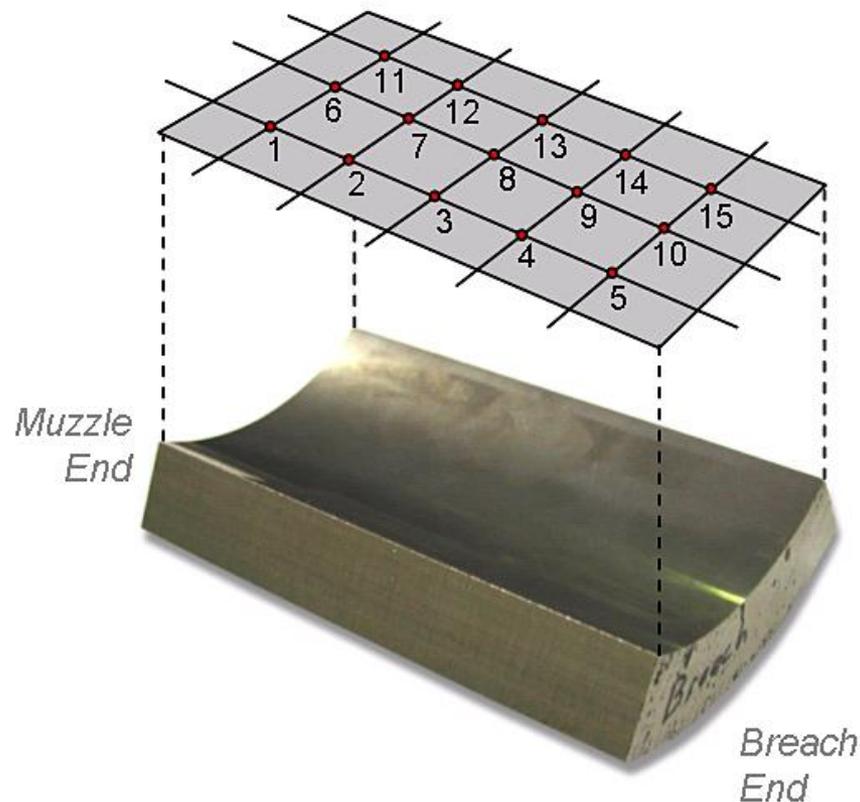
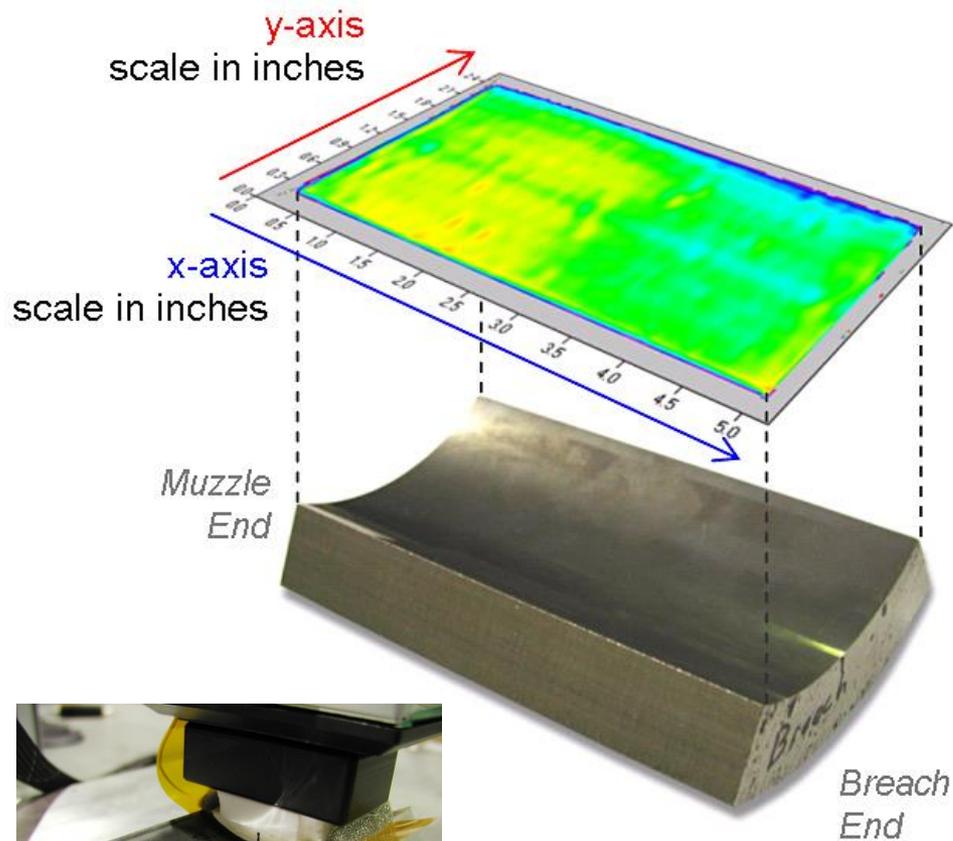
$\mu_s$ ,  $\sigma_s$ ,  $\sigma_{Cr}$ ,  $\delta_{Cr}$  constant



# Schematics of 4-Unknown Constructs



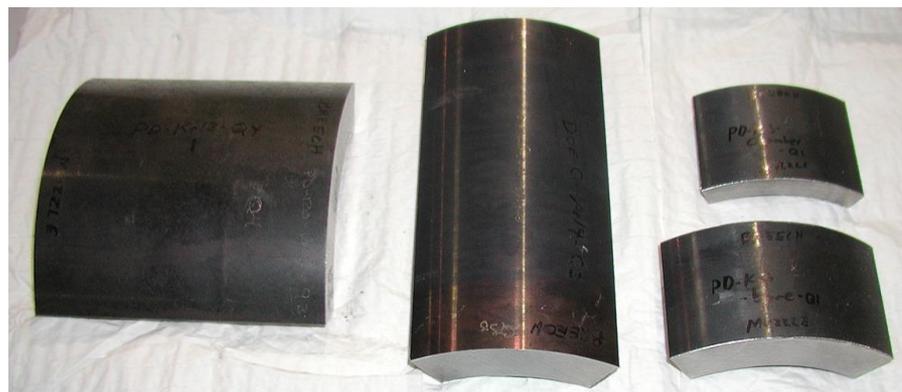
# Example of MWM-Array Conductivity Image and Corresponding Sample



# Matrix of the Samples Analyzed by JENTEK

			Sputtering Gas	
			Ar	Kr
<b>Coating Composition</b>	<b>Majority <math>\alpha</math>-Tantalum</b>	100% Alpha	<b>X</b>	
		100% Alpha <i>with Cr</i>		<b>X</b>
		Mixed Phase (majority alpha)	<b>X</b>	
		Mixed Phase (majority alpha) <i>with Cr</i>		<b>X</b>
	<b>Majority <math>\beta</math>-Tantalum</b>	Mixed Phase (majority beta)		
		Mixed Phase (majority beta) <i>with Cr</i>		
		100% Beta	<b>X</b>	
		100% Beta <i>with Cr</i>		

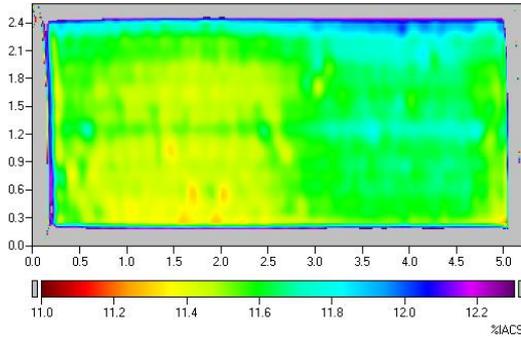
## Samples



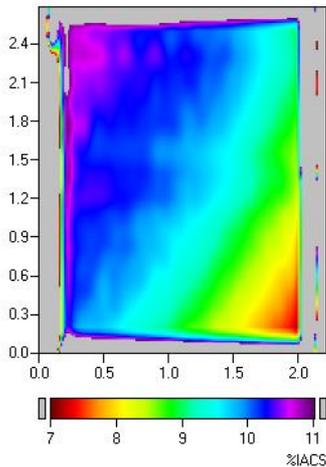
# Examples of MWM-Array Coating Conductivity Images

## Samples Sputtered in Krypton

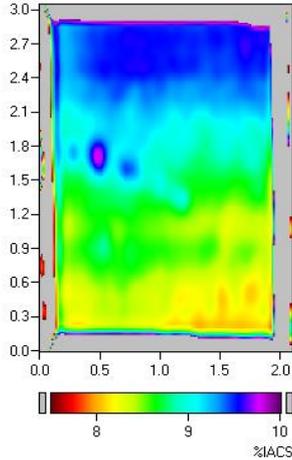
**Sample 4:**  $\alpha$ -Phase Tantalum with Cr Interlayer



**Sample 6:** ( $\alpha + \beta$ ) Tantalum with Cr Interlayer



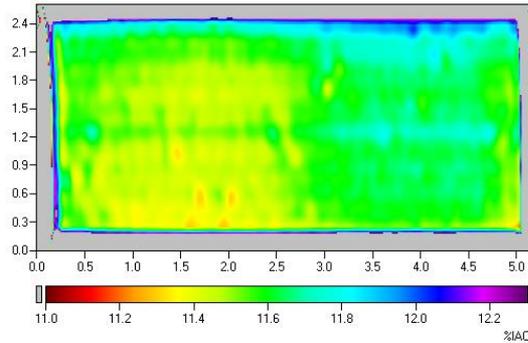
**Sample 7:** ( $\alpha + \beta$ ) Tantalum with Cr Interlayer



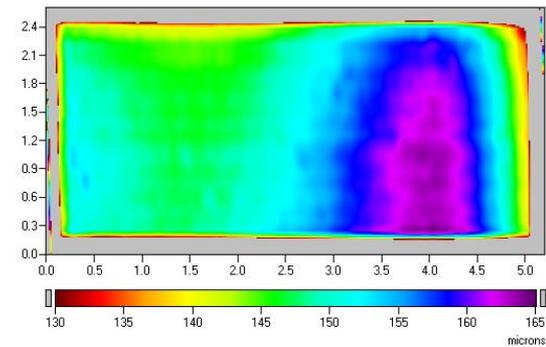
## FA28 Scans - Tantalum Coated Gun Barrel Steel

Sample PD-120-Kr10-Q1, 9% Alpha-Ta with Sputtered Cr Interlayer

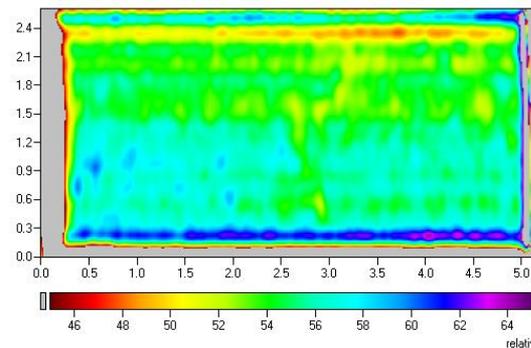
Tantalum Coating Conductivity (*%IACS*)



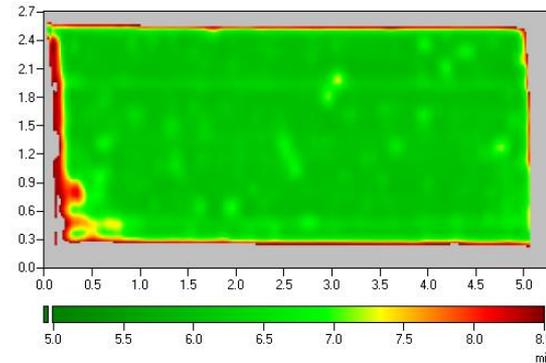
Tantalum Coating Thickness (*microns*)



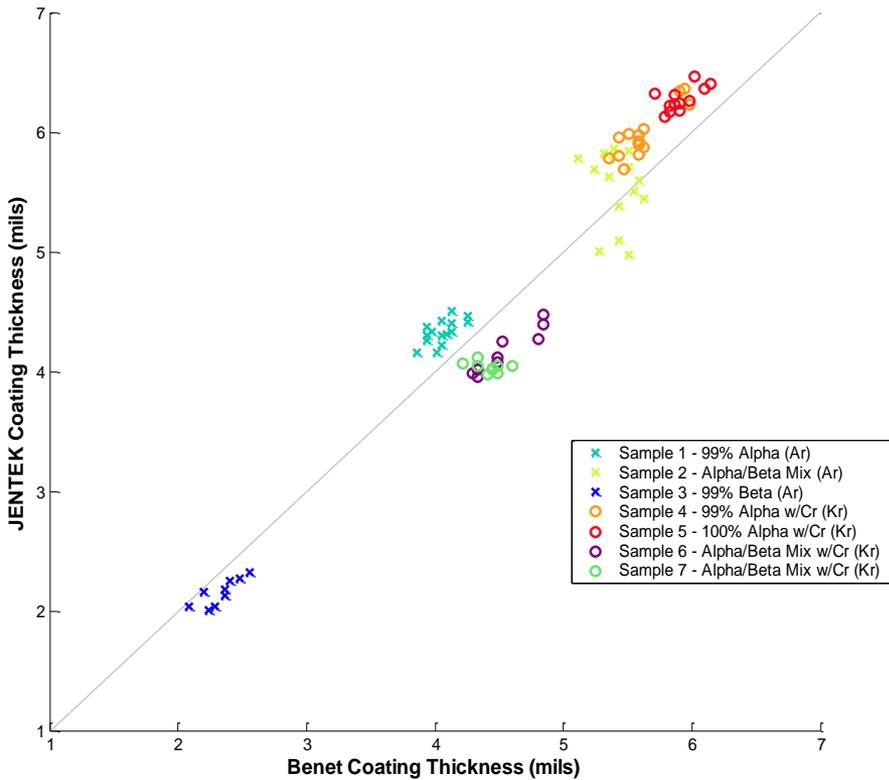
Steel Substrate Permeability (*rel*)



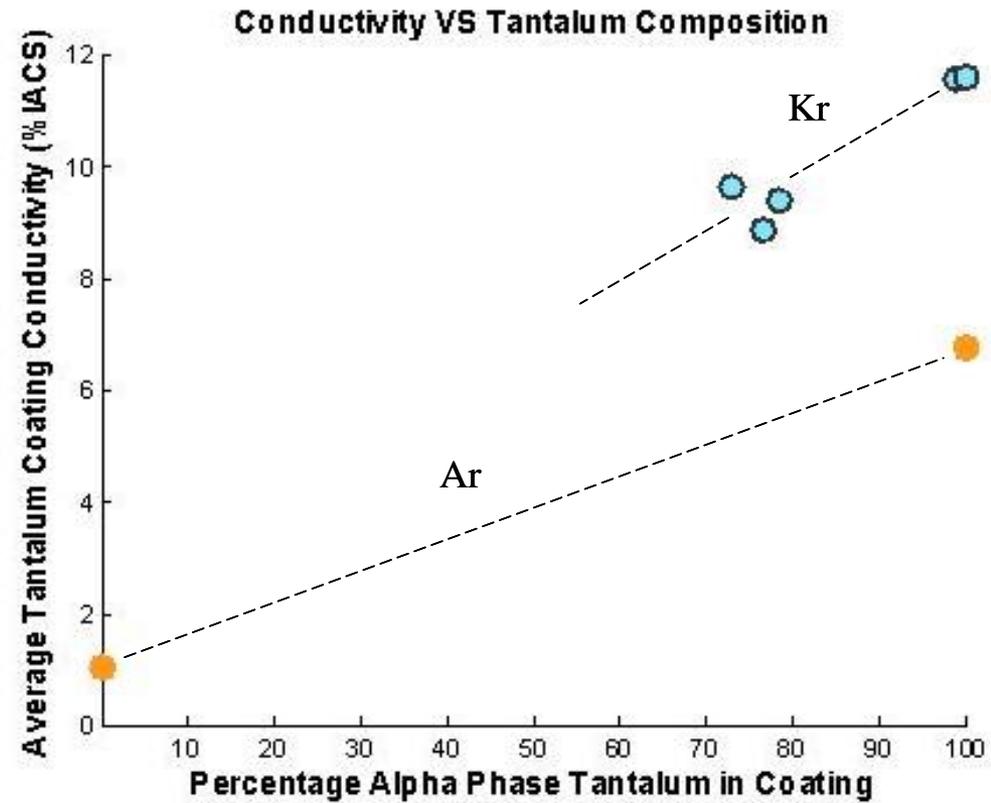
Lift-Off (*mils*)



## MWM-Array Measured Tantalum Coating Thickness Values



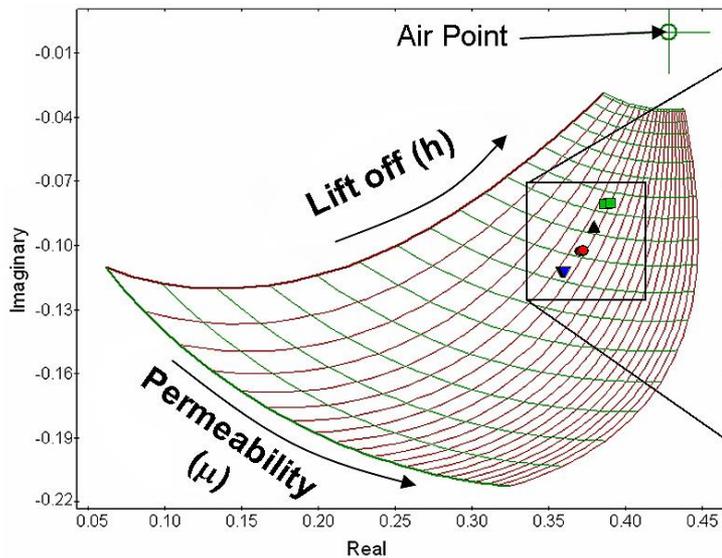
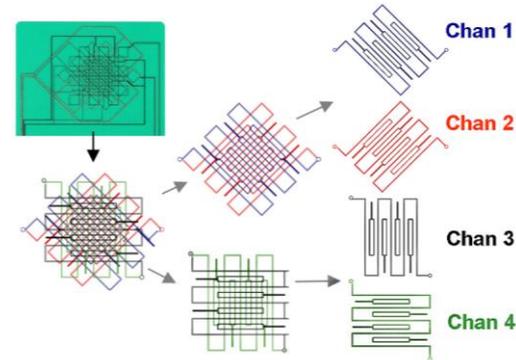
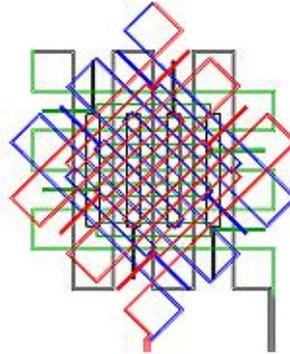
## Conductivity vs. Phase Composition for Tantalum Coatings



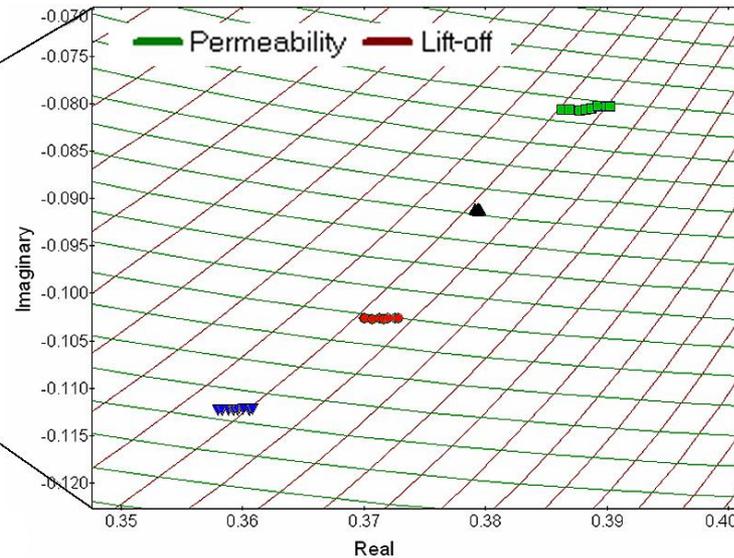
# Quadri-Directional Magnetic Stress Gage (QD-MSG)



$$\text{Transinductance} = \frac{V_2}{j\omega i_1} = \text{Re} \left( \frac{V_2}{j\omega i_1} \right) + j \text{Im} \left( \frac{V_2}{j\omega i_1} \right)$$

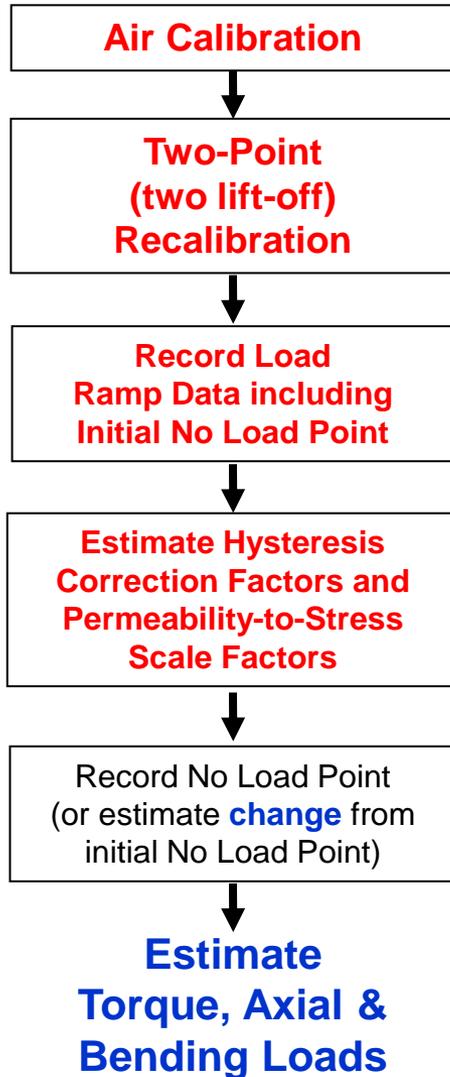


Imaginary vs. Real – 1 MHz – (Moving Average, n=1000), (Grid at 1 MHz)

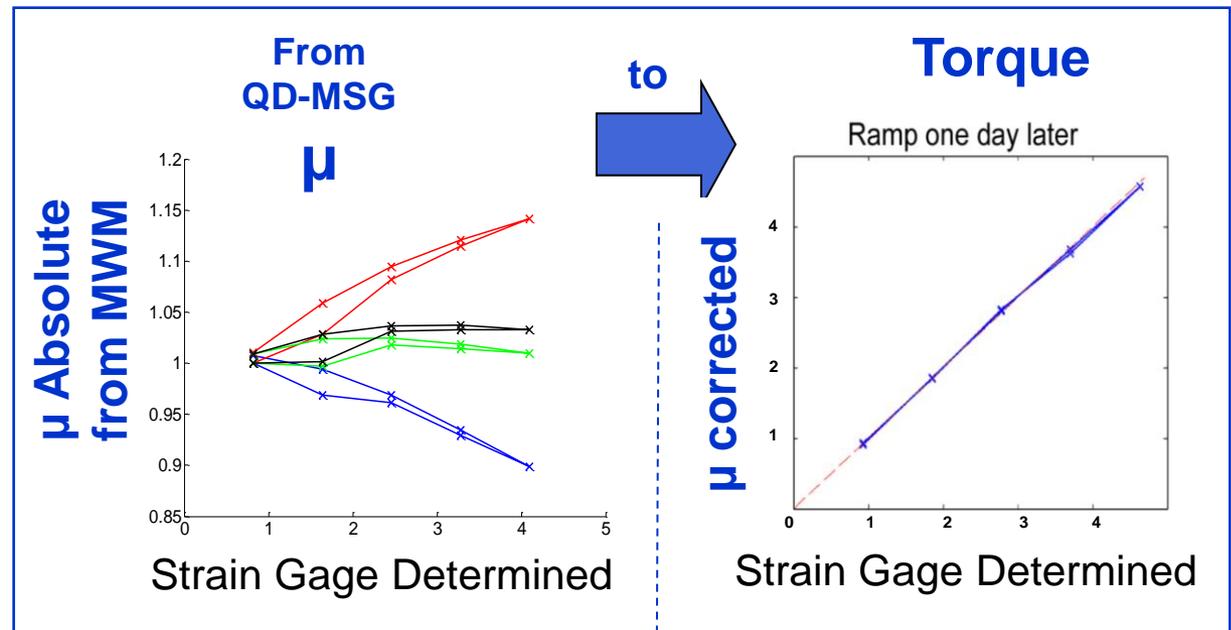


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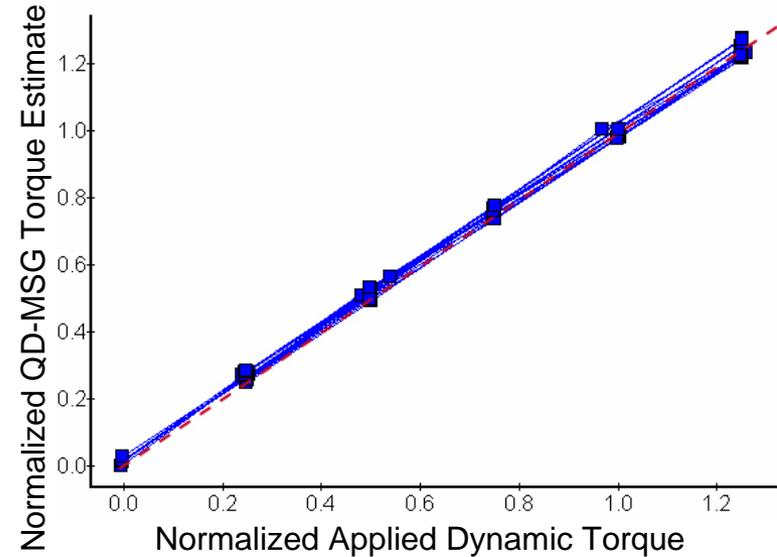
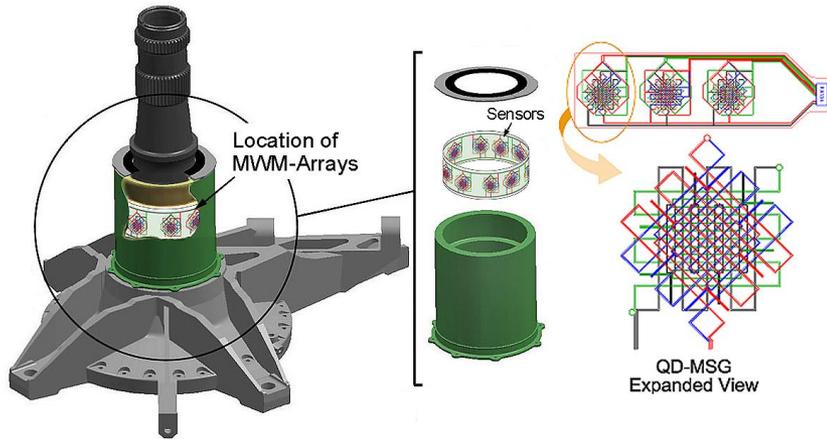
# QD-MSG Dynamic, Non-Contact Torque Measurement Procedure



## Hysteresis Correction (after temperature correction)



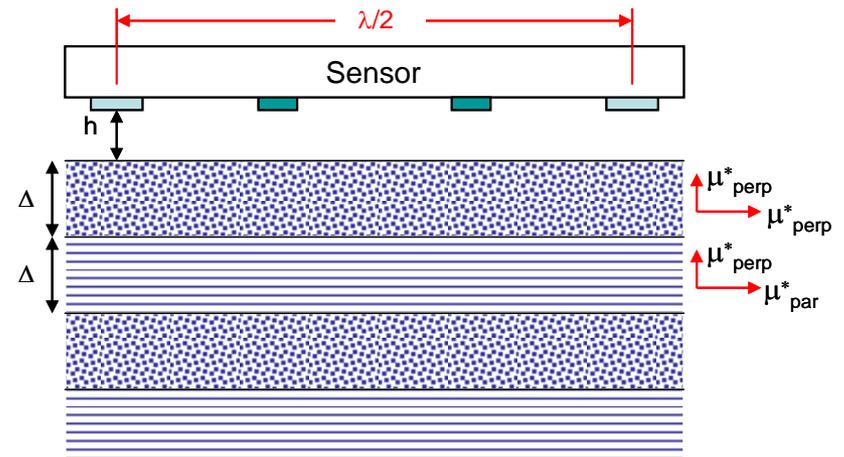
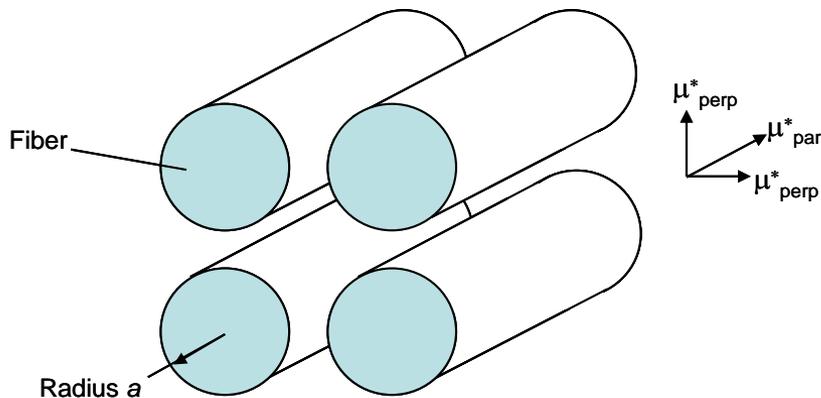
# Sensor Installation for Full Scale Testing at Boeing, Philadelphia



**Two Successful Full Scale Tests Completed**

# Eddy Current Micromechanical Model (for Composites)

- **Eddy current extension of micromechanical models**
  - Uniaxial fiber bundle model that accounts for magnetic field interactions with the fibers in each orientation.
  - Effective complex permeability accounts for frequency dependence and anisotropic material properties
- **In the process of incorporating the composite model into rapid layered media models.**



# A Two Part Presentation

**Dr. Neil Goldfine**

## **Introduction to:**

- Design, Calibration, Measurement, Inverse Methods, Filters, Decisions
- MWM and MWM-Array Sensors & IDED and IDED-Array Sensors
- Applications (cracks, coatings, corrosion, stress, temperature)
  - Grids and Lattices for Multivariate Inverse Methods
  - Air and Reference Calibration
  - Signature Libraries & Time-Sequenced Imaging for Enhanced Detection

**Motivation  
&  
Applications**

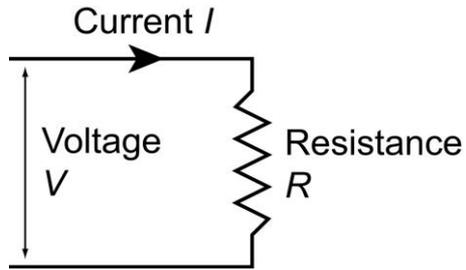
**Dr. Yanko Sheiretov**

## **Background on:**

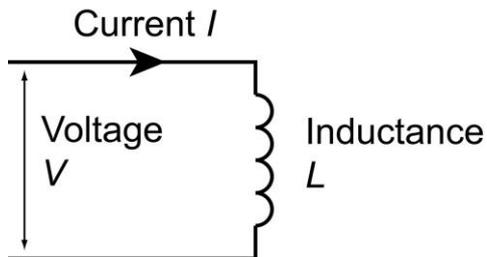
- Sensor Model
  - Two-port Impedance Matrices, Transimpedance, Maxwell's Equations, Quasistatic Regimes, EM-field Partial Differential Equations and Solutions
- Multivariate Inverse Methods
  - Searching in multi-dimensional nonlinear spaces
  - Multi-dimensional nonlinear interpolation

**Physics  
&  
Details**

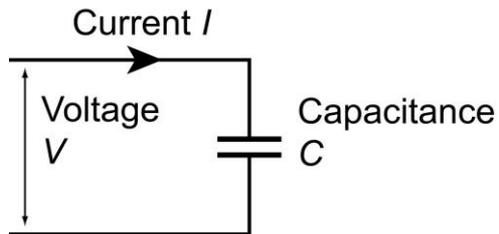
# Basic Circuit Elements



$$V = RI \quad (\text{Ohm's Law})$$



$$V = L \frac{dI}{dt}$$



$$I = C \frac{dV}{dt}$$

# Complex Impedance

Sinusoidal Steady State

$$f(t) = F \cos(2\pi ft + \phi) \quad \longrightarrow \quad f(t) = \Re \left\{ \hat{F} e^{j2\pi ft} \right\} = \Re \left\{ F e^{j(2\pi ft + \phi)} \right\}$$

$$F = \text{magnitude, } \phi = \text{phase, } f = \text{frequency} \quad \hat{F} = F e^{j\phi}$$

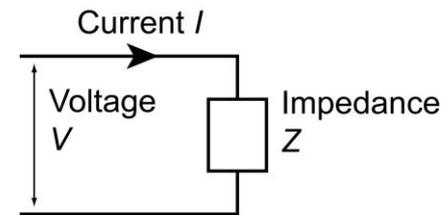
$$V = RI \quad \longrightarrow \quad \hat{V} = R\hat{I}$$

$$V = L \frac{dI}{dt} \quad \longrightarrow \quad \hat{V} = j2\pi fL\hat{I}$$

$$I = C \frac{dV}{dt} \quad \longrightarrow \quad \hat{V} = \frac{1}{j2\pi fC} \hat{I}$$

Everything can be treated as a simple resistor, using complex numbers

$$\hat{V} = \hat{Z}\hat{I}$$

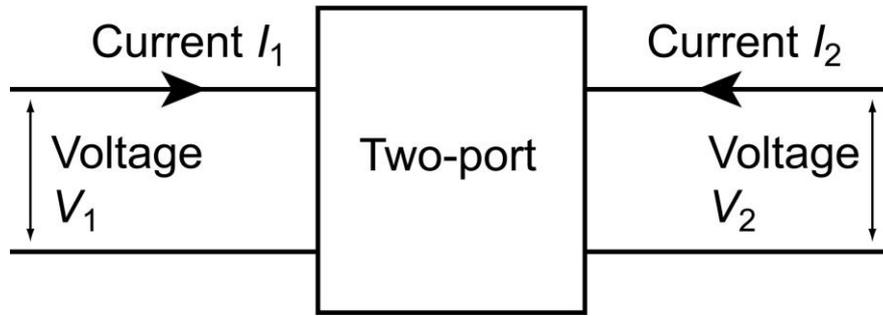


$$\frac{d}{dt} \quad \longrightarrow \quad j2\pi f$$

Drop the hats (^) from now on

# Two-port Impedance Matrices, Transimpedance

It is difficult to measure the voltage and current at the same set of terminals;  
*...this is why the MWM and IDED use secondary windings/electrodes.*



Impedance matrix:

$$\begin{pmatrix} V_1 \\ V_2 \end{pmatrix} = \begin{pmatrix} Z_{11} & Z_{12} \\ Z_{21} & Z_{22} \end{pmatrix} \begin{pmatrix} I_1 \\ I_2 \end{pmatrix}$$

↑ *transimpedance*

$$\begin{pmatrix} Y_{11} & Y_{12} \\ Y_{21} & Y_{22} \end{pmatrix} = \begin{pmatrix} Z_{11} & Z_{12} \\ Z_{21} & Z_{22} \end{pmatrix}^{-1} \quad Y_{21} \neq Z_{21}^{-1}$$

$$\begin{pmatrix} I_1 \\ I_2 \end{pmatrix} = \begin{pmatrix} Y_{11} & Y_{12} \\ Y_{21} & Y_{22} \end{pmatrix} \begin{pmatrix} V_1 \\ V_2 \end{pmatrix}$$

↑ *transadmittance*

$$\left. \begin{array}{l} \text{MWM: } I_2 = 0 \Rightarrow V_2 = Z_{21} I_1 \\ \text{IDED: } V_2 = 0 \Rightarrow I_2 = Y_{21} V_1 \end{array} \right\}$$

*The sensors and instrument are designed in a way that requires only one matrix element to be computed.*

# Maxwell's Equations, Quasistatic Regimes

$$\nabla \cdot \epsilon \mathbf{E} = \rho \quad \text{Gauss' Law}$$

$$\nabla \cdot \mu \mathbf{H} = 0$$

$$\nabla \times \mathbf{E} = -\frac{\partial \mu \mathbf{H}}{\partial t} \quad \text{Faraday's Law}$$

$$\nabla \times \mathbf{H} = \mathbf{J} + \frac{\partial \epsilon \mathbf{E}}{\partial t} \quad \text{Ampère's Law}$$

$$\nabla \cdot \mathbf{J} + \frac{\partial \rho}{\partial t} = 0 \quad \text{Charge conservation}$$

## Magnetoquasistatic (MWM)

Ignore changing electric fields

Eddy Currents!  
↓

$$\nabla \cdot \mu \mathbf{H} = 0 \quad \nabla \times \mathbf{H} = \mathbf{J} \quad \nabla \times \mathbf{E} = -\frac{\partial \mu \mathbf{H}}{\partial t}$$

If we let  $\mu \mathbf{H} = \nabla \times \mathbf{A}$  and  $\mathbf{J} = \sigma \mathbf{E}$   
(Ohm's Law)

$$\nabla^2 \mathbf{A} = \mu \sigma \frac{\partial \mathbf{A}}{\partial t}$$

Magnetic Diffusion Equation

## Electroquasistatic (IDED)

Ignore changing magnetic fields

$$\nabla \cdot \epsilon \mathbf{E} = \rho \quad \nabla \times \mathbf{E} = 0 \quad \nabla \cdot \mathbf{J} + \frac{\partial \rho}{\partial t} = 0$$

If we let  $\mathbf{E} = -\nabla \Phi$  then

$$\nabla^2 \Phi = -\frac{\rho}{\epsilon}$$

Poisson's Equation

# EM-field Partial Differential Equations and Solutions

Writing the equations with complex number notation:

Magnetoquasistatic (MWM)

$$\nabla^2 \mathbf{A} = j2\pi f \mu \sigma \mathbf{A}$$

Electroquasistatic (IDED)

$$\nabla^2 \Phi = 0 \quad (\text{no free charge, } \rho = 0)$$

Solving these equations in general is very difficult. However, if we assume that:

- The sensor is periodic in the  $x$ -direction with period (wavelength)  $\lambda$
- Nothing changes in the  $y$ -direction and currents flow in the  $y$ -direction
- The materials are uniform

then we can find some “simple” solutions (periodic in  $x$ , exponential in  $z$ ):

$$\mathbf{A} \propto \begin{Bmatrix} \cos(2\pi x/\lambda) \\ \sin(2\pi x/\lambda) \end{Bmatrix} \begin{Bmatrix} \exp(\gamma z) \\ \exp(-\gamma z) \end{Bmatrix} \mathbf{i}_y$$

$$\gamma = \sqrt{(2\pi/\lambda)^2 - j2\pi f \mu \sigma} = \sqrt{(2\pi/\lambda)^2 - 2j/\delta^2}$$

$$\delta = \sqrt{1/\pi f \mu \sigma} \quad (\text{skindepth})$$

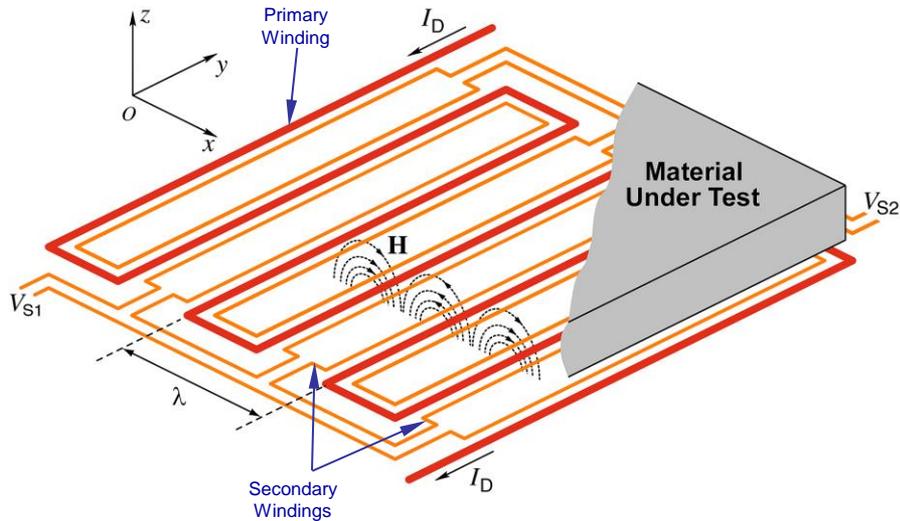
$$\Phi \propto \begin{Bmatrix} \cos(2\pi x/\lambda) \\ \sin(2\pi x/\lambda) \end{Bmatrix} \begin{Bmatrix} \exp(\gamma z) \\ \exp(-\gamma z) \end{Bmatrix}$$

$$\gamma = 2\pi/\lambda$$

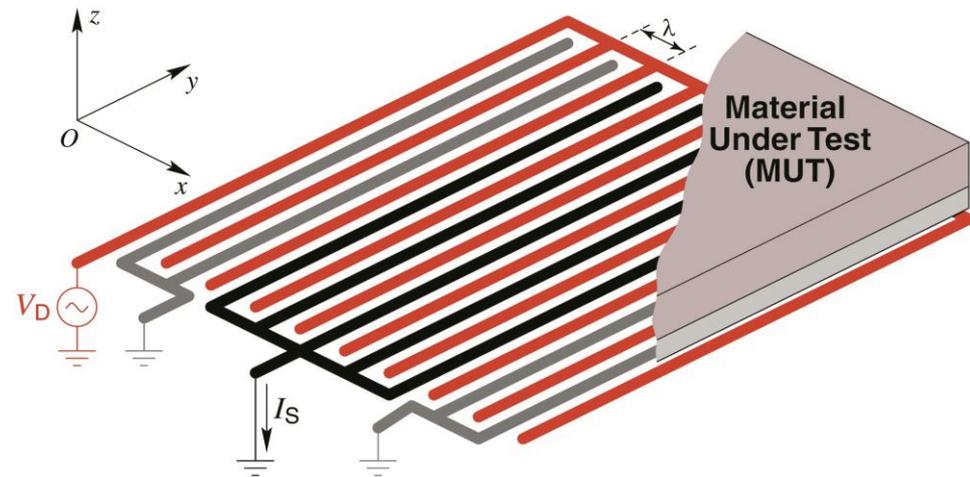
*In the dielectric case, the **depth of sensitivity**,  $1/\gamma$ , does not depend on frequency.*

# Sensor Structure, Periodicity, Wavelength, and Fourier Series

## Magnetoquasistatic (MWM)



## Electroquasistatic (IDED)

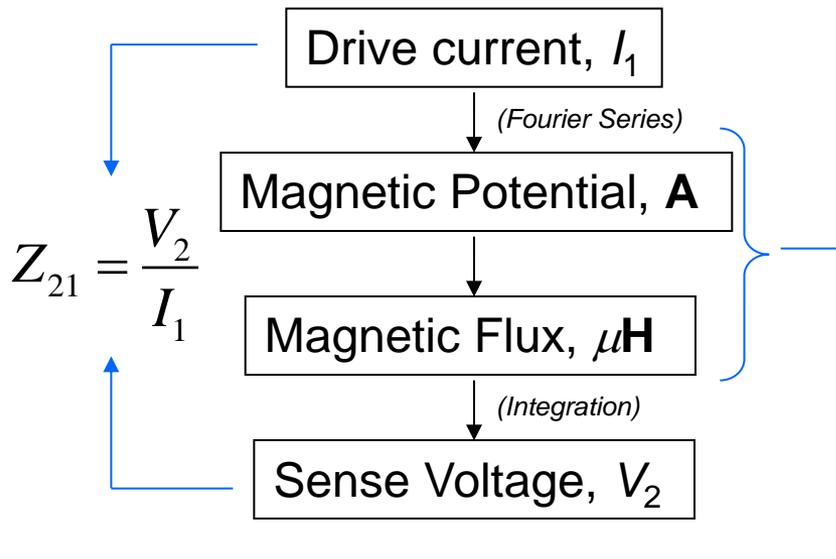


The sensors are designed to fit the assumptions that make it possible to use the simple solutions (periodic, with dummy elements that make them look infinite, etc.).

They are periodic, but **not** sinusoidal. Solution: break the solution up into a **sum** of sinusoids with wavelengths  $\lambda$ ,  $\lambda/2$ ,  $\lambda/3$ , etc., using **Fourier Series**, solve for each separately, then put the solution back together at the end.

# Computing Transimpedance, Surface Reluctance/Capacitance Density

## Magnetoquasistatic (MWM)

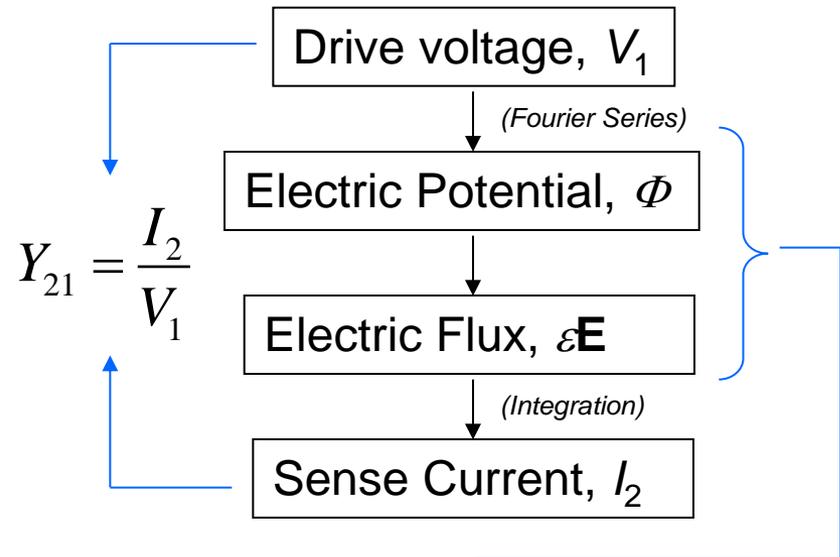


$$H_x = RA_y =$$

$R$  contains all the information about the material properties and geometry. At the bottom of an infinitely thick layer,

$$R = \frac{\gamma}{\mu}$$

## Electroquasistatic (IDED)

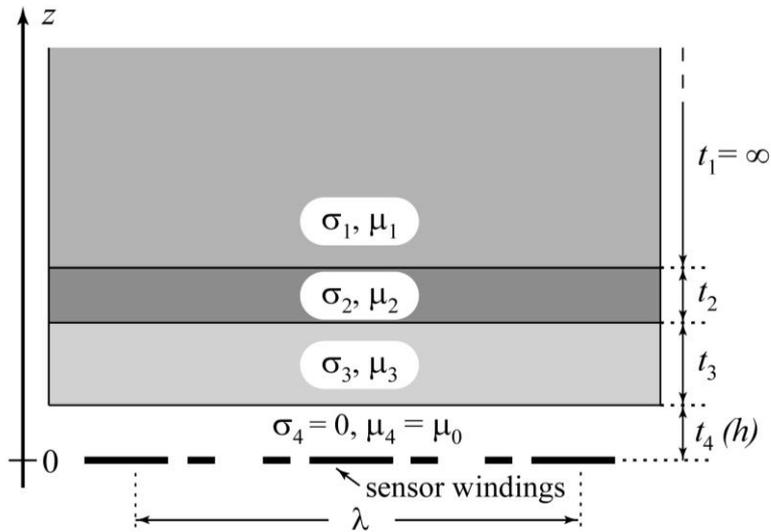


$$\epsilon E_z = C\Phi$$

$C$  contains all the information about the material properties and geometry. At the bottom of an infinitely thick layer,

$$C = \gamma\epsilon = \frac{2\pi}{\lambda}\epsilon$$

# Matching Boundary Conditions, Multiple Layers, and Transfer Relations



At every layer interface:

- The potential must be continuous
- The flux must be continuous

This lets us match the solutions in every layer. It turns out that if we know  $R$  or  $C$  at the top of a layer, we can obtain it at the bottom.

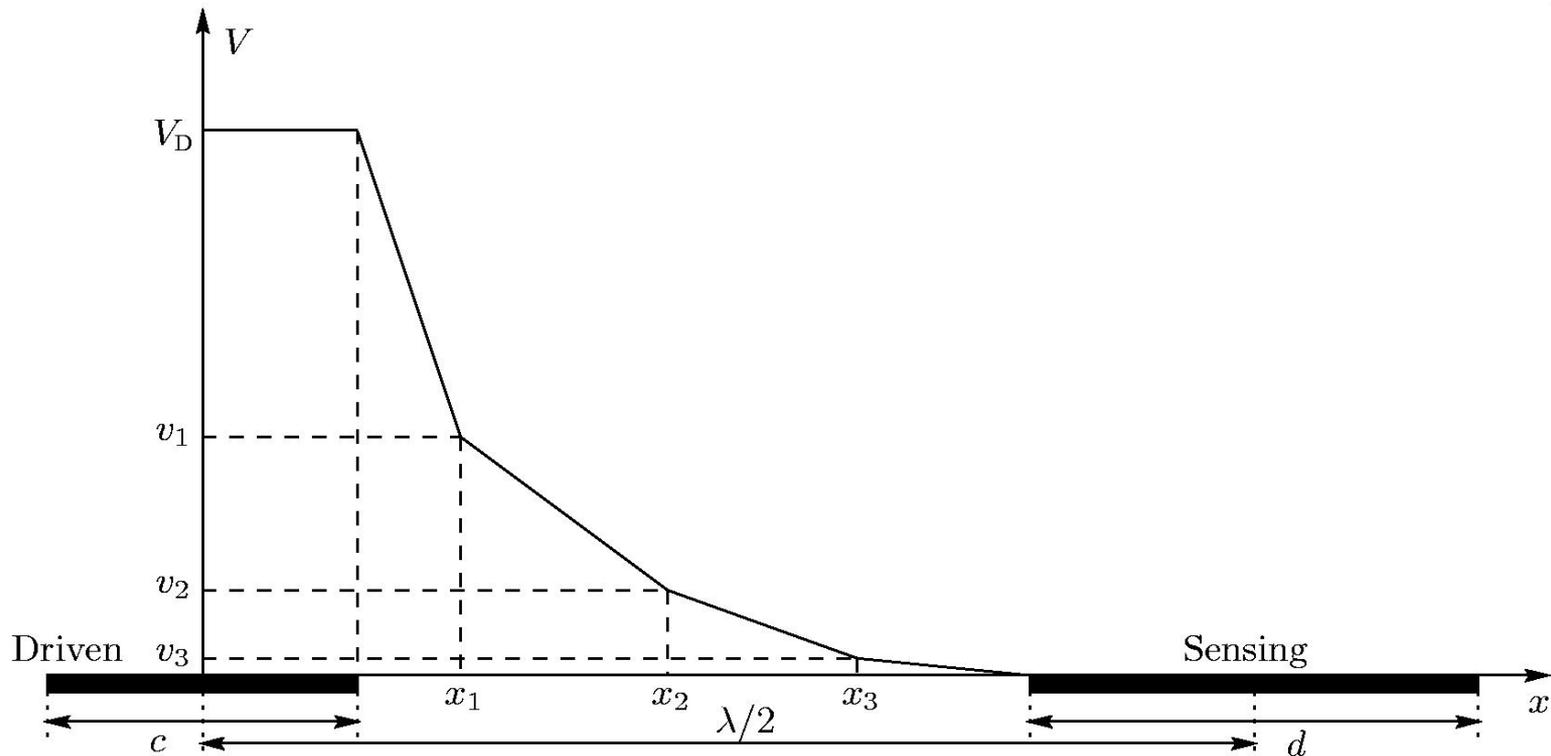
$$R_{\text{bottom}} = \frac{\gamma}{\mu} \cdot \frac{\mu R_{\text{top}} \coth(\gamma t) + \gamma}{\mu R_{\text{top}} + \gamma \coth(\gamma t)}$$

$$C_{\text{bottom}} = \gamma \epsilon \cdot \frac{C_{\text{top}} \coth(\gamma t) + \gamma \epsilon}{C_{\text{top}} + \gamma \epsilon \coth(\gamma t)}$$

In this way, all information about all material layers is contained in a single quantity:  $R$  or  $C$  at the sensor windings or electrodes.

# Collocation Point Method

Approximates the unknown potential as an interpolation between its values at a set of points, called the **collocation points**. These values are computed by solving a set of simultaneous equations, each of which is derived from a boundary condition applied over a spatial interval that contains the corresponding collocation point.

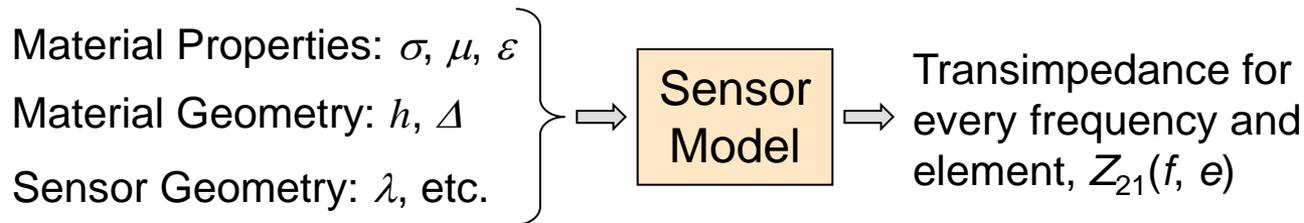


# Multivariate Inverse Methods

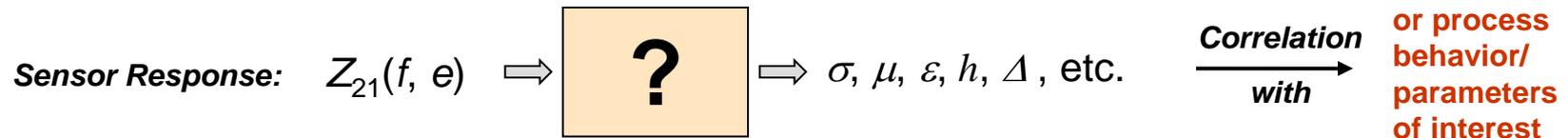
- The Need for Inverse Interpolation
- Approaches to Solving the Inverse Problem
- One-Dimensional Inverse Interpolation
- Two-Dimensional Inverse Interpolation
- Interpolation and Extrapolation Methods
- Overconstrained Problems
- Summary

# The Need for Inverse Interpolation

## Forward problem:



## Inverse problem:

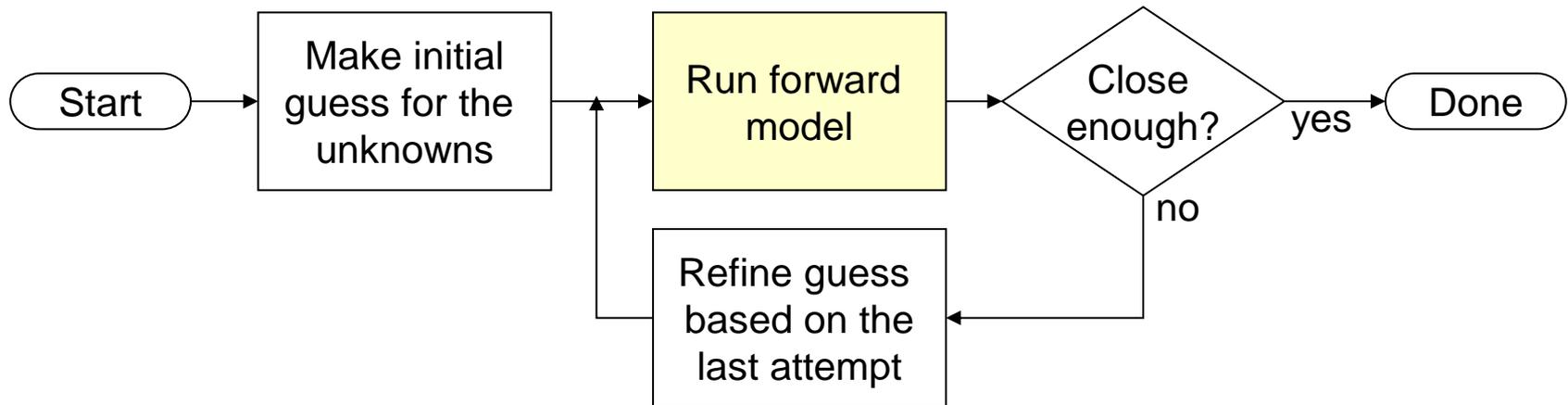


- If the number of unknowns is equal to the number of “equations” or “knowns” (two for every frequency/element combination), it *might* be possible to find an exact solution.
- In general, we are looking for a set of values for the unknowns that will yield the best match to the measured transimpedances.

In general, it is not possible to solve the inverse problem in “closed form,” i.e., derive direct formulas or methods.

# Approaches to Solving the Inverse Problem

*The inverse problem must be solved iteratively:*



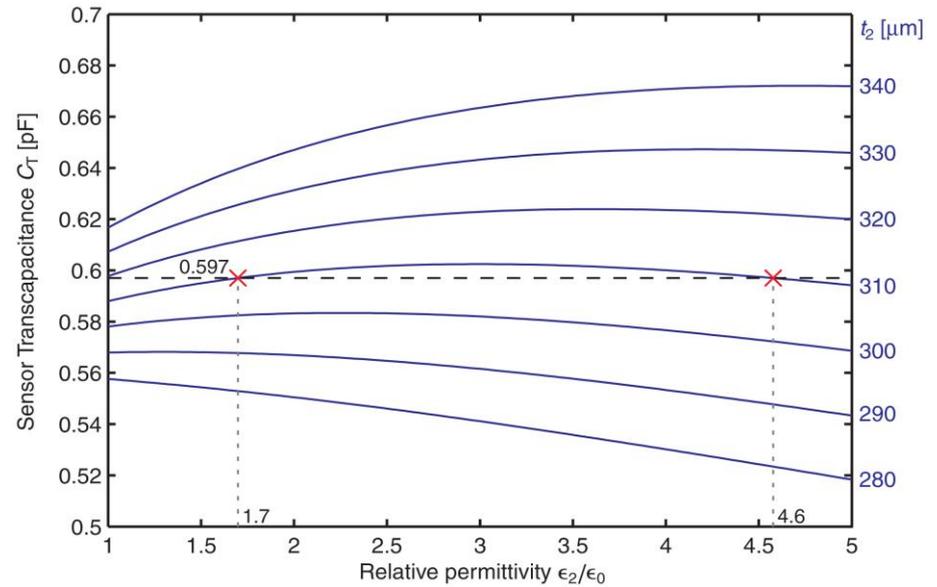
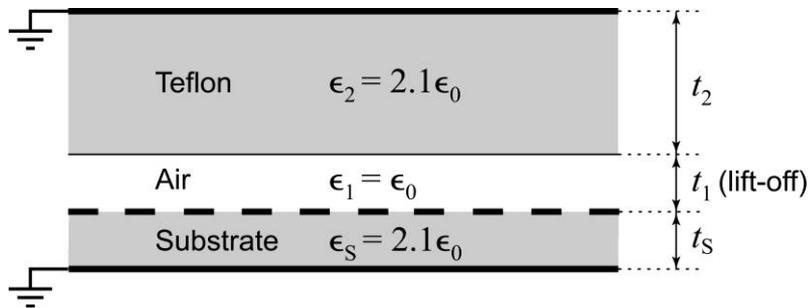
*Problems with this approach:*

- Requires the client/user to have access to the tools that implement the forward model.
- It is slow, not suited for real-time applications.
- Not guaranteed to converge to a solution even if one exists.
- At the end of the estimation, any knowledge collected along the way is lost.

*Solution: generate (off-line) a database of precomputed sensor responses and then find the answer via inverse interpolation.*

# One-Dimensional Inverse Interpolation

Example: single-wavelength  
IDED used to measure  
dielectric permittivity.



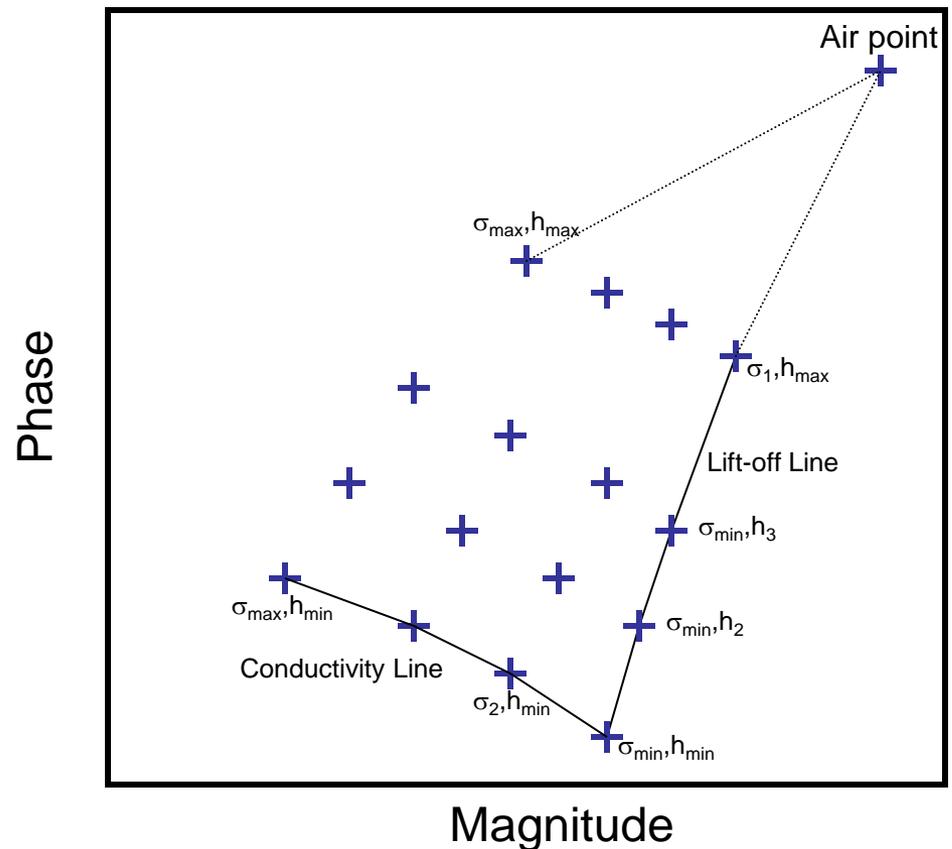
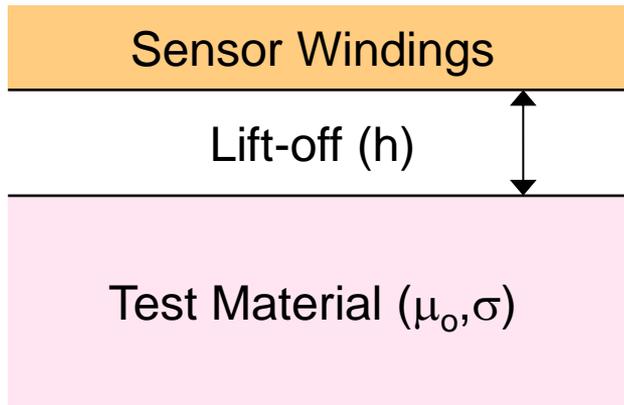
- Forward interpolation (using the curves to get  $C_T$  from  $\epsilon_2$ ) is easy.
- Inverse interpolation (using the curves to get  $\epsilon_2$  from  $C_T$ ) is hard: there can be one, two, or no solutions.

...but at least we can see this right away, by traversing the curve and seeing if we encounter the transcapacitance value.

*This cannot be done in two or more dimensions!*

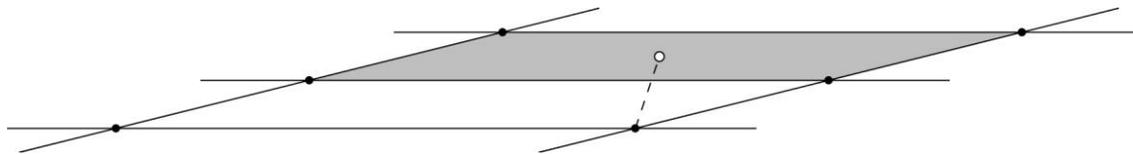
# Measurement Grids

- Create a database of responses prior to data acquisition for the range of properties of interest
  - In two-dimensions, can be plotted as a grid

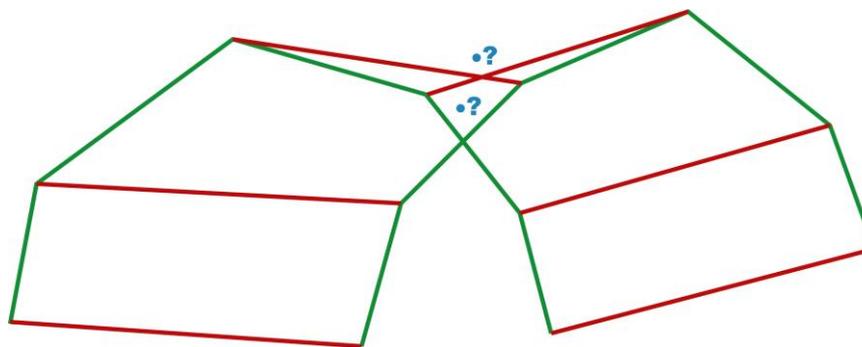


# Examples of Two-Dimensional Inverse Interpolation Issues

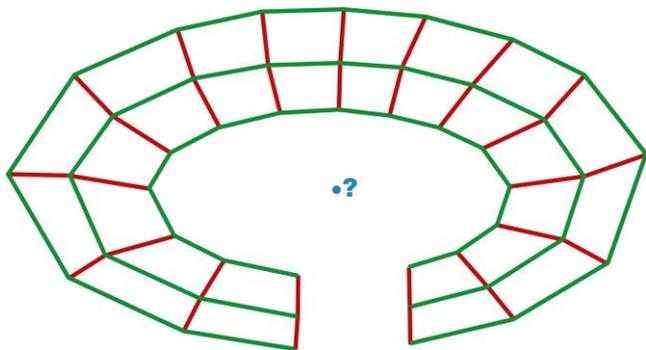
Closest point is not necessarily correct (happens all the time).



What to do when edges cross (happens all the time).



Are we "on the grid"?



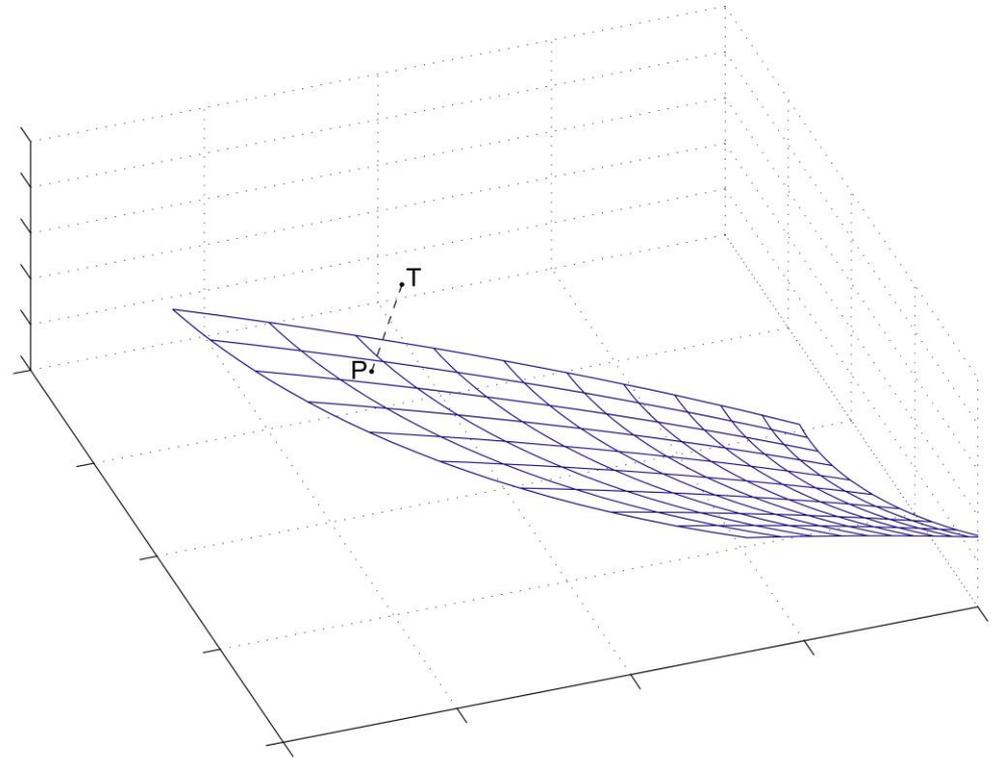
*The hardest thing to do is determining whether a point is on the grid and which grid cell to use for interpolation.*

# Overconstrained Problems (more equations than unknowns)

Every grid cell defines a (hyper) space via the direction vectors associated with each property.

If the target point does not lie in this space, we work with its **orthogonal projection**.

This is **guaranteed to produce the best solution** in the least squares sense.



Example: 2-D grid in 3-D impedance space. Point P is the orthogonal projection of point T onto the plane of the particular grid cell

# Matrix of Partial Derivatives, Pseudoinverse, and Singular Value Decomposition

Let  $k_1 \dots k_n$  be the unknowns and  $z_1 \dots z_m$  be the impedance measurements (i.e., “equations”). The Jacobian matrix defines the directions in impedance space in which each of the unknown properties change.  $m \geq n$

$$\Delta \mathbf{z} = \mathbf{M} \cdot \Delta \mathbf{k}$$

$$\mathbf{M} = \begin{bmatrix} \frac{\partial z_1}{\partial k_1} & \frac{\partial z_1}{\partial k_2} & \dots & \frac{\partial z_1}{\partial k_n} \\ \frac{\partial z_2}{\partial k_1} & \frac{\partial z_2}{\partial k_2} & \dots & \frac{\partial z_2}{\partial k_n} \\ \vdots & \vdots & \ddots & \vdots \\ \frac{\partial z_m}{\partial k_1} & \frac{\partial z_m}{\partial k_2} & \dots & \frac{\partial z_m}{\partial k_n} \end{bmatrix}$$

Direction vector of increasing  $k_2$

where  $\Delta \mathbf{z}$  is the vector connecting the reference point (origin) to the target point and  $\Delta \mathbf{k}$  are the property estimate offsets from the property values at the reference point.

If  $\mathbf{P}$  is the **pseudoinverse** matrix of  $\mathbf{M}$  then

$$\Delta \mathbf{k} = \mathbf{P} \cdot \Delta \mathbf{z} \quad \mathbf{P} = (\mathbf{M}^T \mathbf{M})^{-1} \mathbf{M}^T$$

The pseudoinverse  $\mathbf{P}$  is computed via **Singular Value Decomposition**. If any of the singular values are zero (or very small) then the matrix  $\mathbf{M}$  is singular and the **selectivity** at this grid point is low, i.e., the unknown properties are not independent.

$$\mathbf{M} = \mathbf{U} \mathbf{W} \mathbf{V}^T \rightarrow \mathbf{P} = \mathbf{V} \mathbf{W}^{-1} \mathbf{U}^T$$

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# Questions?

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